

Sources of intense beams of heavy ions

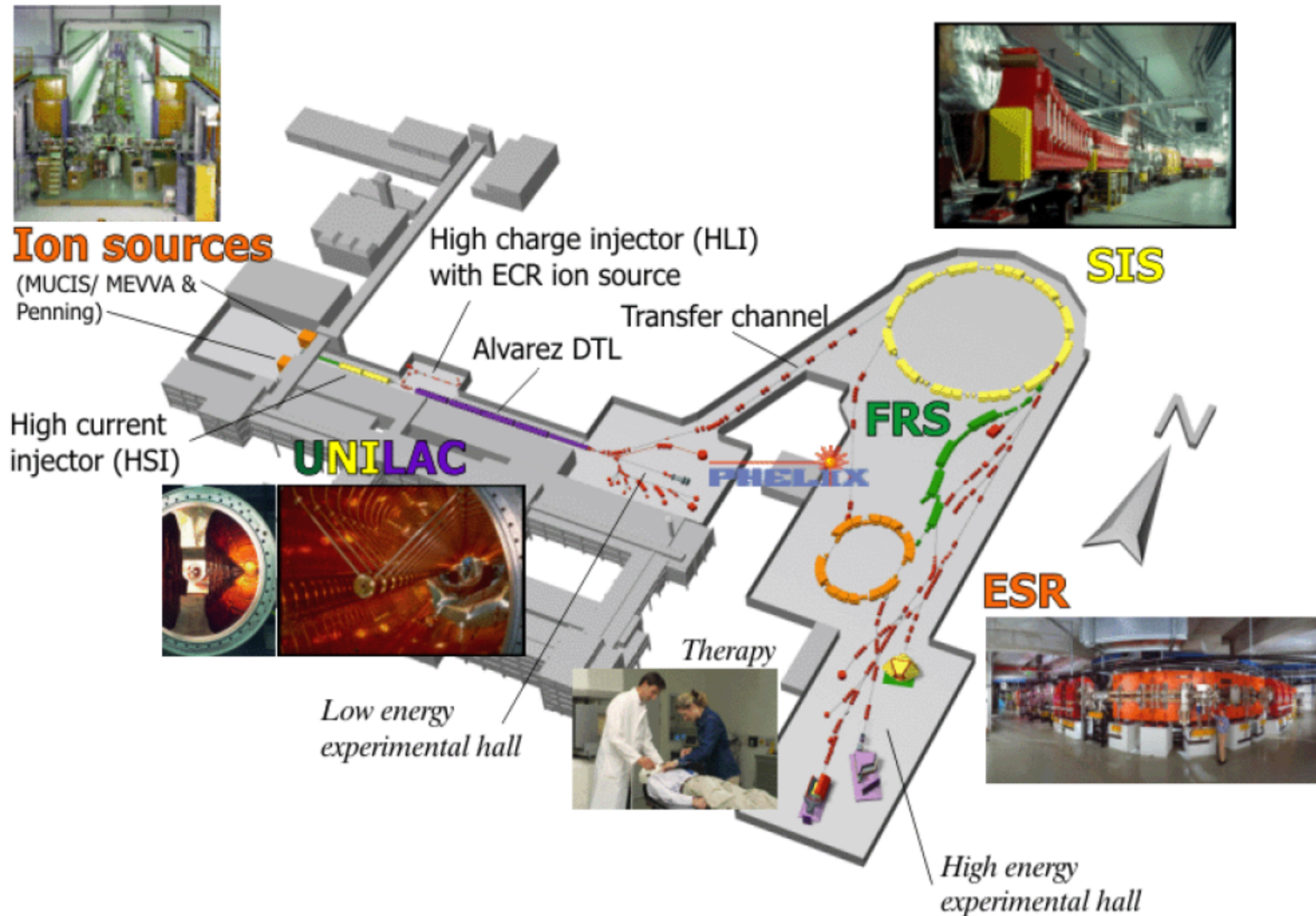


517. WE-Heraeus-Seminar Accelerator physics for intense ion beams

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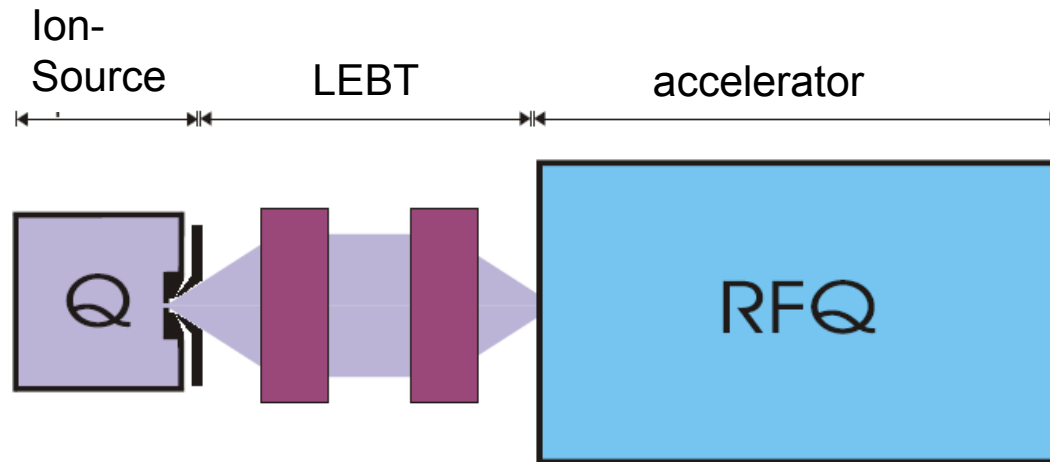
Heavy ion accelerator facility



Outline

- Introduction and Basics
 - Ionisation, plasma generation
 - confinement and extraction of ions
- High current ions sources
 - Multi-cups ion sources
 - rf-driven ion sources
 - Metal vapor vacuum arc sources (MeVVA)
- High charge state ion sources
 - The Electron Cyclotron Resonance Ion Sources (ECRIS)
 - The Electron Beam Ion Source (EBIS)

Ion sources – accelerator application

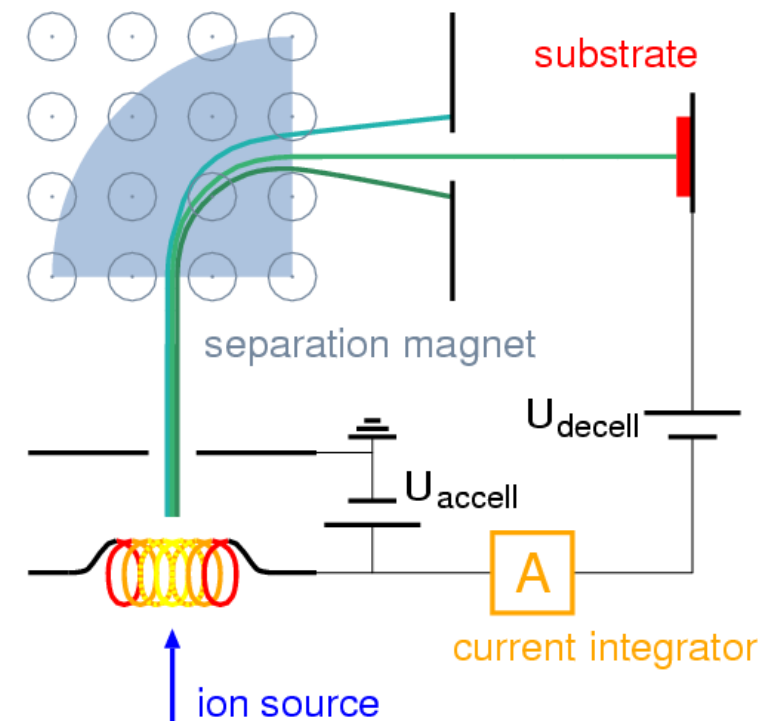


Ion implanter

Penetration depth $\rightarrow$ beam energy
Intense ion source $\rightarrow$ volume ion sources

For semiconductor production

Typical structure
of an injection line:





Introduction and Basics

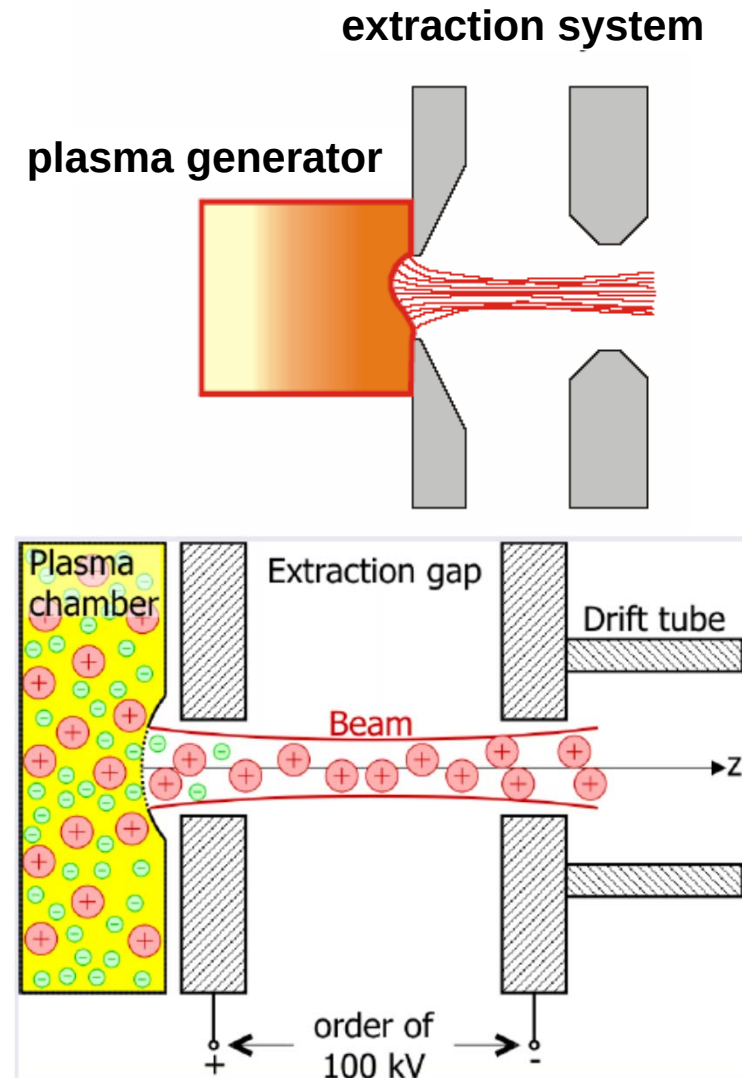
Physics of ion sources?

The physics of ion sources:

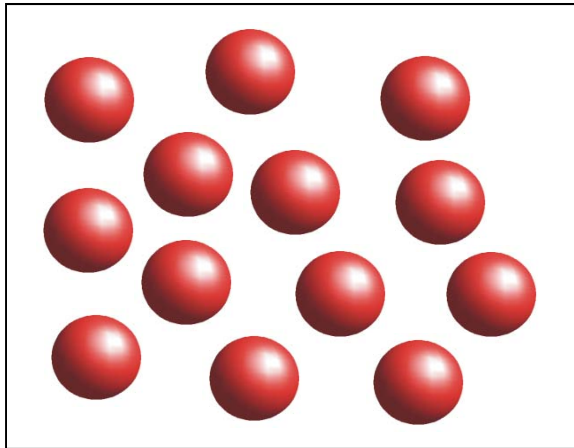
- Ionisation of atoms (Electron impact ionisation, photoionization)
- Production of charged particles (Electrons, ions) → Production of plasma
- Plasma physics
- Beam shaping and charged particle transport
- Electromagnetic fields (electric, magnetic, rf)

Principle of a plasma ion source:

- plasma generation
- extraction

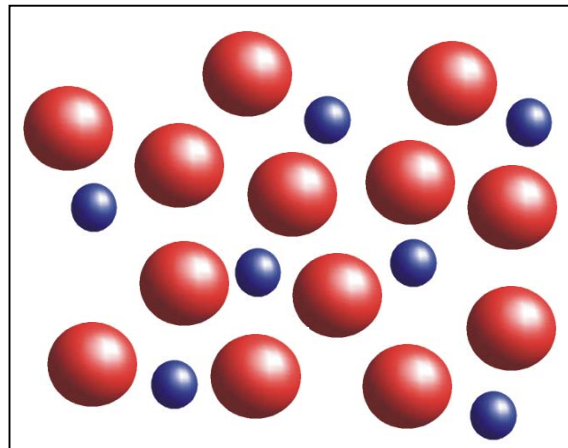


Plasma generation



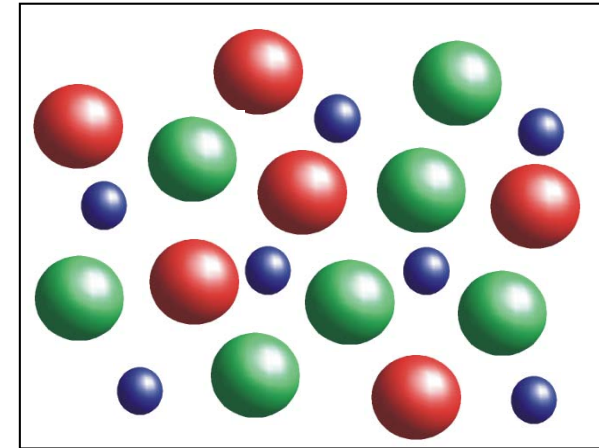
Make atoms available in the plasma generator via:

- Gas injection
- Vapour, melting of solids
- Sputtering



Generate free electrons:

- Thermionic emission
- Photo ionisation
- Discharge



Supply the ionisation energy:

- Electron acceleration (electrostatic → e-gun)
- rf-heating
- E x B-drift

Atomic processes in a Plasma

electrons
collisions with

Impact Ionization



Impact excitation

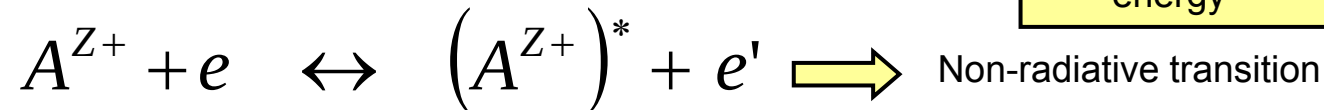
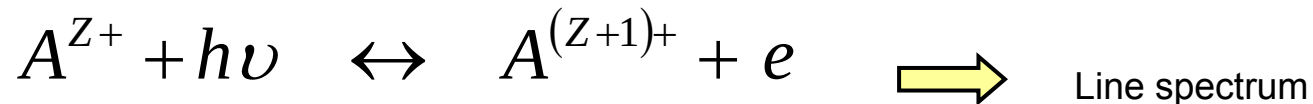


Photo ionization



Excitation

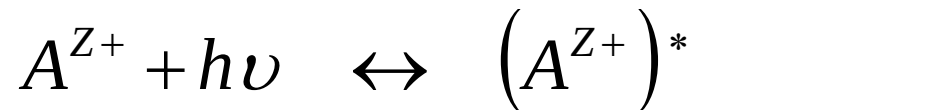
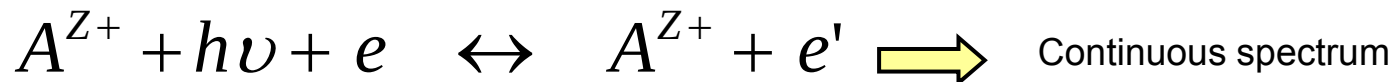


Photo absorption



Three-Body-Recombination (TBR)

Impact de-excitation

Radiative Recombination (RR)

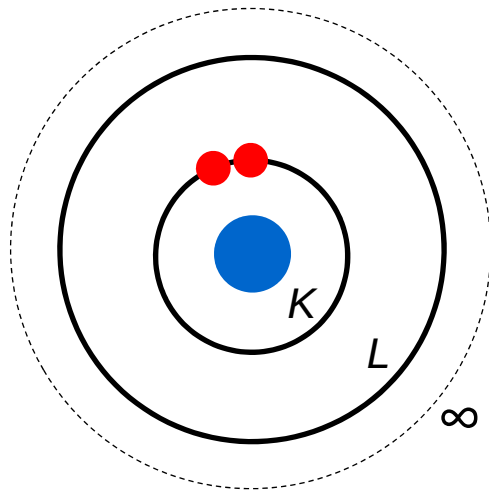
Spontaneous emission

Bremsstrahlung

A^{Z+} : Atom of species A
with charge state Z
 e' : electron changed
energy

Electron impact Ionisation

The electron impact ionization is the most fundamental ionization process for the operation of ion sources.



electron impact ionisation



The probability for removing one electron ($q \rightarrow q+1$) is determined by the cross section $\sigma_{q \rightarrow q+1}$ [cm²].

$$\bar{\tau}_{q \rightarrow q+1} = \frac{n_q}{v_{q \rightarrow q+1}} = \frac{1}{n_e v_e \sigma_{q \rightarrow q+1}} = \frac{e}{j_e \sigma_{q \rightarrow q+1}}$$

The average ionization time in the charge state q depends only on the cross section and the current density of the electrons.

e-impact ionisation cross section

Approximation of the cross section in quantum-mechanical calculations done by Bethe (1930) using the Born Approximation:

Scattering of a matter wave at a central potential $V(r)$ for $E_{\text{kin}} \gg E_{\text{ion}}$ (perturbation).

$$\sigma_i^{nl} = \text{const} \cdot Z_{nl} \frac{1}{E_{\text{kin}} E_{nl}} \ln \left(\frac{E_{\text{kin}}}{E_{nl}} \right)$$

All electrons in an atom or ion contribute with their individual σ_{ei} to the total cross section σ , as long as the kinetic energy E_{kin} of the projectile is larger than the ionization energy E_{nl} of these electrons.

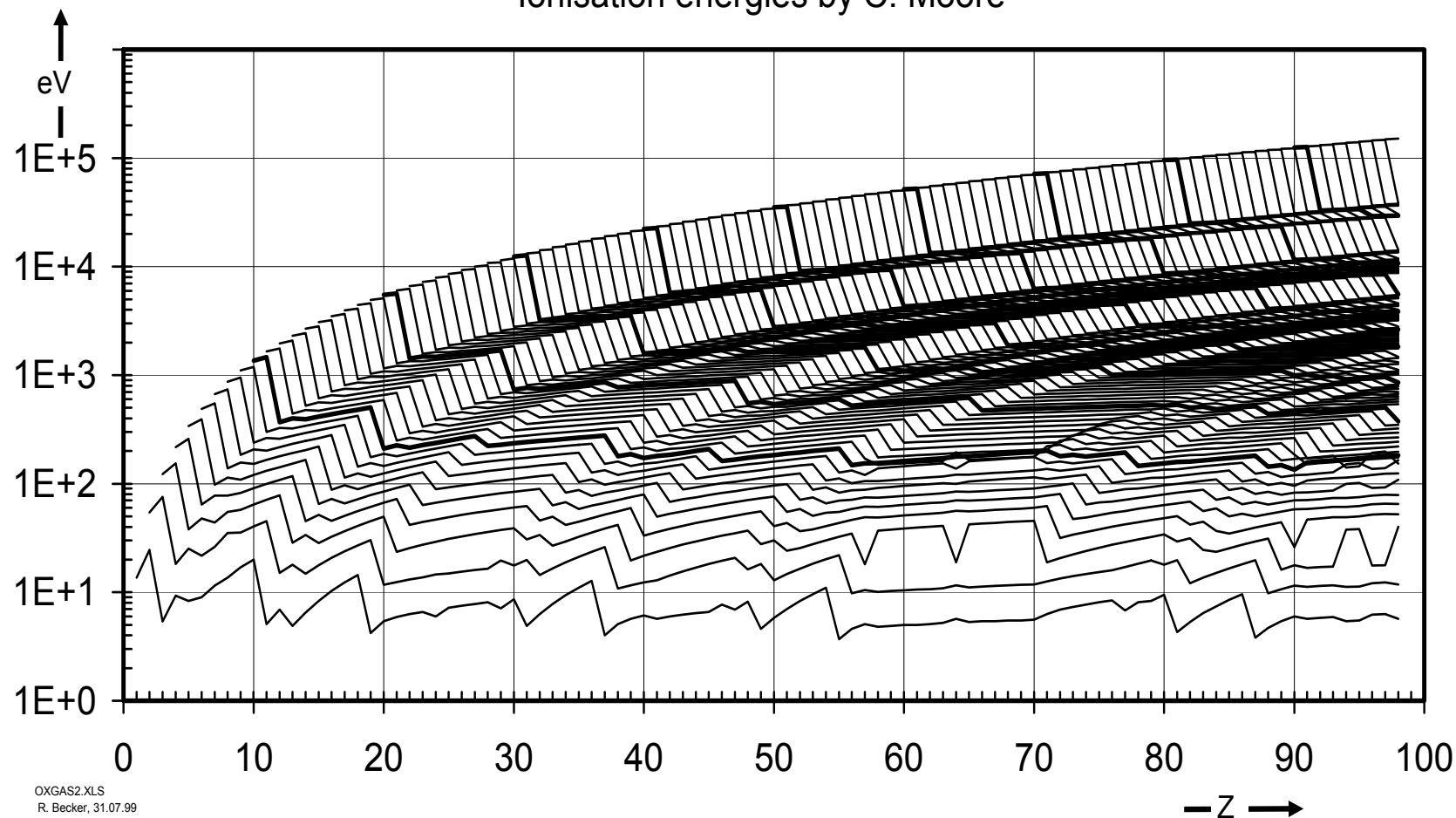
$$\sigma_{q \rightarrow q+1} = \sum_{i=1}^N \sigma_i = \sum_{i=1}^N q_i \sigma_{ei}$$

Semi-empirical formula developed by **Lotz 1967** for the energy dependence of the cross sections for the elements from H to Ca and for energies < 10 keV is commonly used.

$$\sigma_{q \rightarrow q+1} = 4.5 \cdot 10^{-14} \cdot \sum_{i=1}^N \frac{\ln \left(\frac{E_{\text{kin}}}{P_i} \right)}{E_{\text{kin}} \cdot P_i} \quad [\text{cm}^2]$$

Ionisation potential

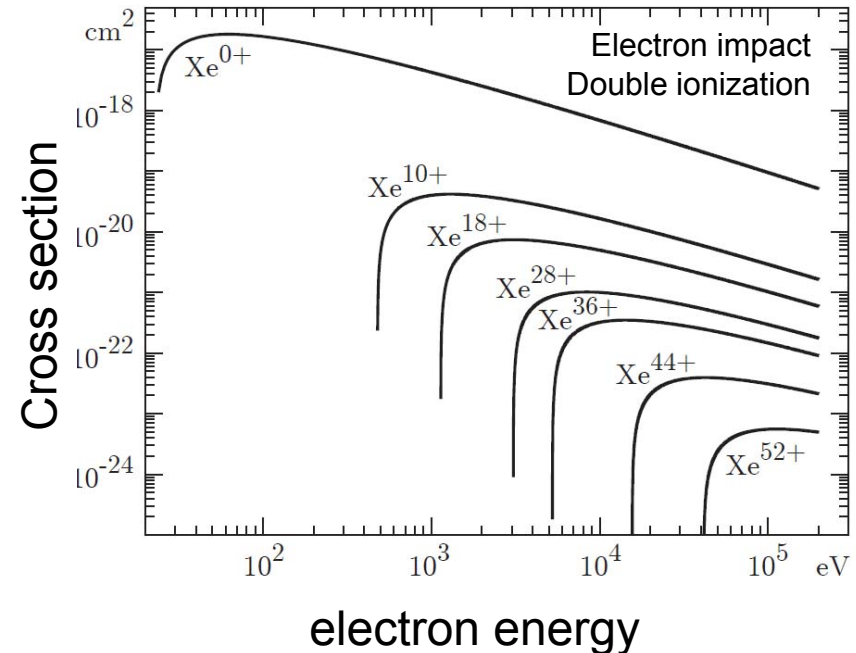
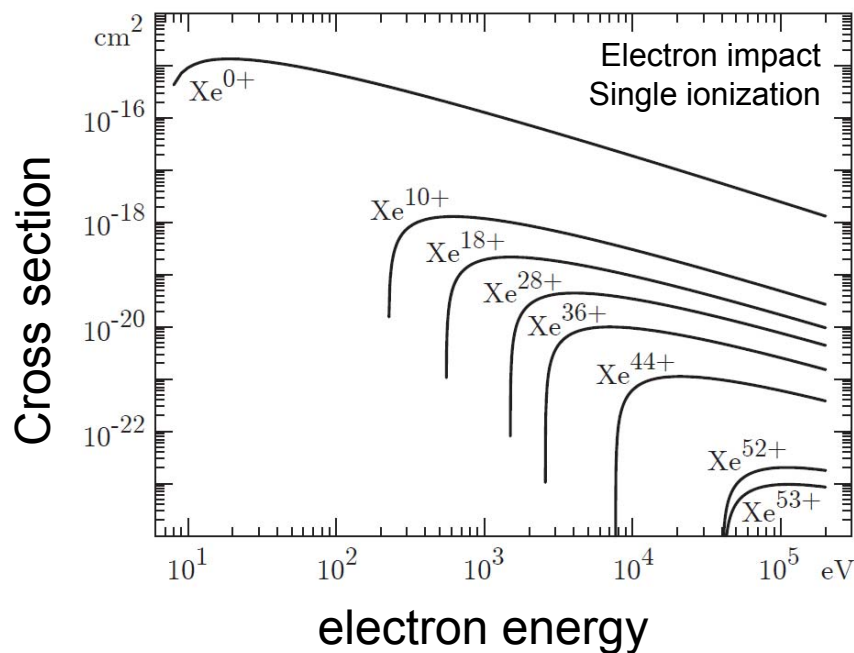
Ionisation energies by C. Moore



- Ionization energies up to 100 keV ($U^{91+} \rightarrow U^{92+}$) required
- Shell structure of the atomic shells is visible

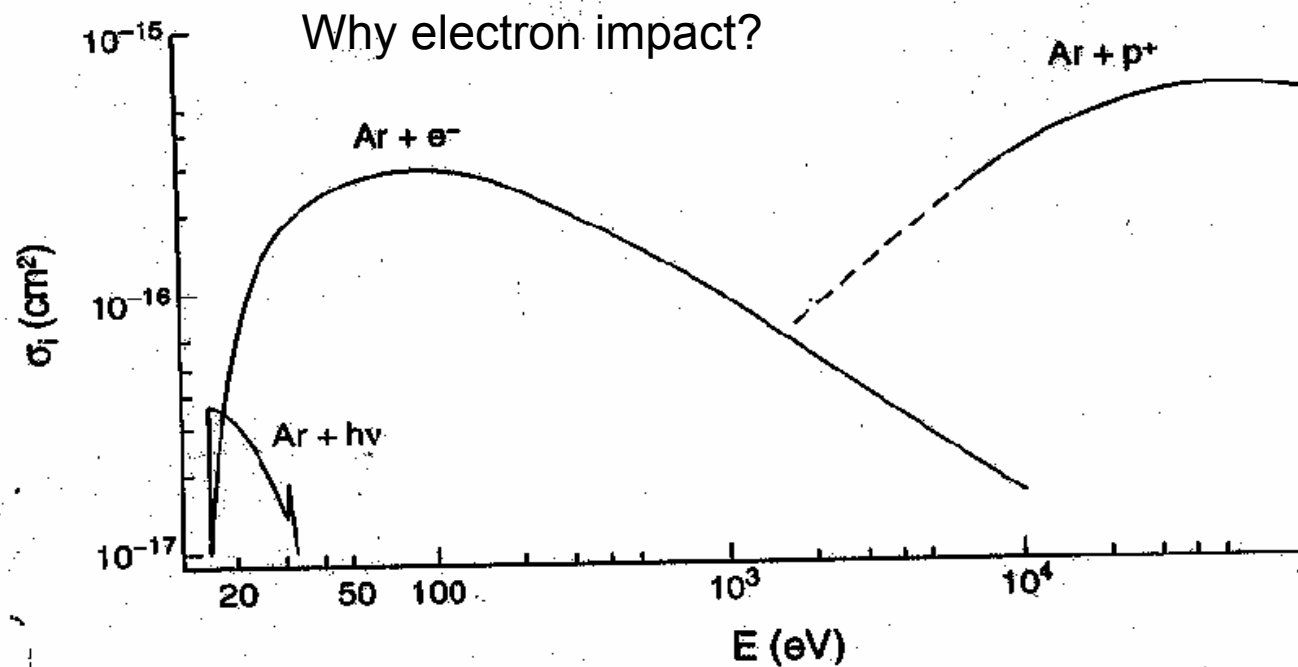
Successive e-impact ionisation

Multi electron removal or single electron successive ionization?



Single step → much higher cross section

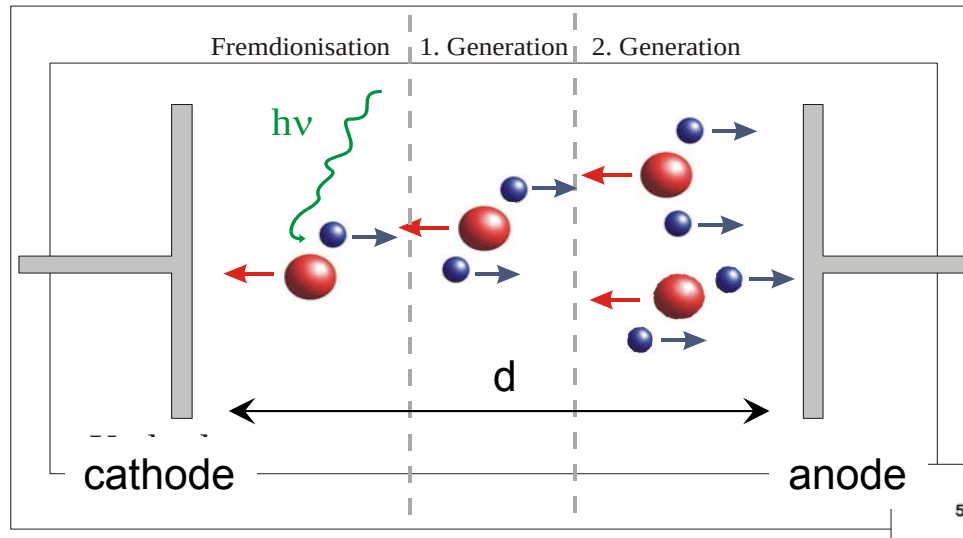
Successive e-impact ionisation



The cross section for the impact ionization is orders of magnitudes higher than the cross section for photo ionization.

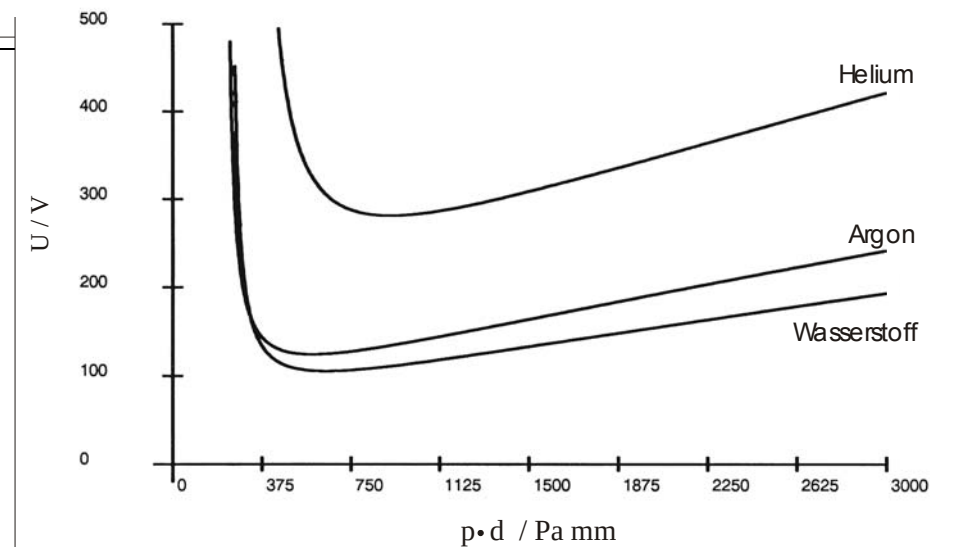
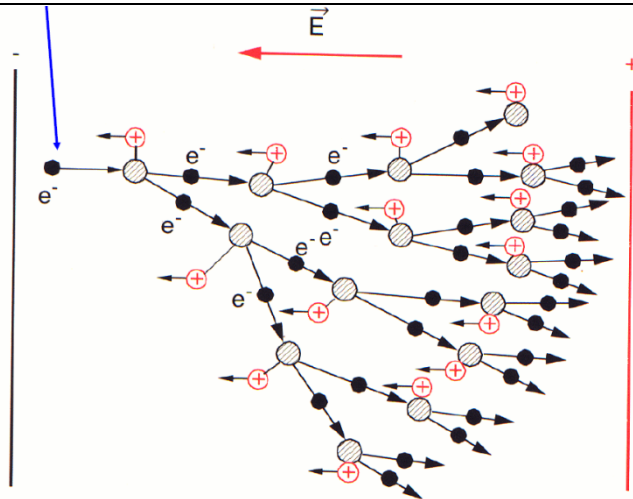
The cross section depends on the mass of the colliding particle, since the energy transfer from a heavy projectile is reduced.

Plasma generation - discharge

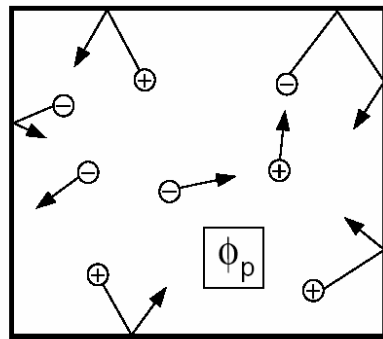


The discharge depends on the gas pressure and the electric field strength

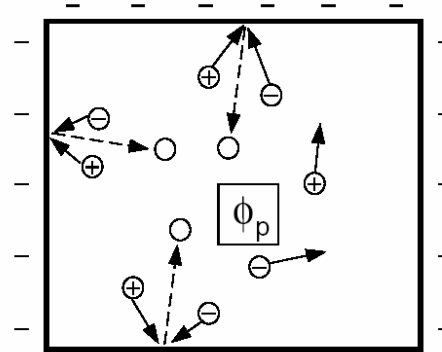
→ Paschen curve



Plasma potential and potential distribution



$$\phi_{\text{wand}} = 0$$

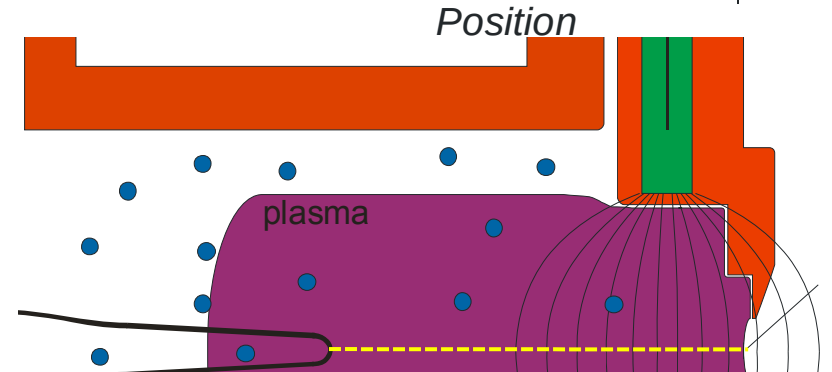
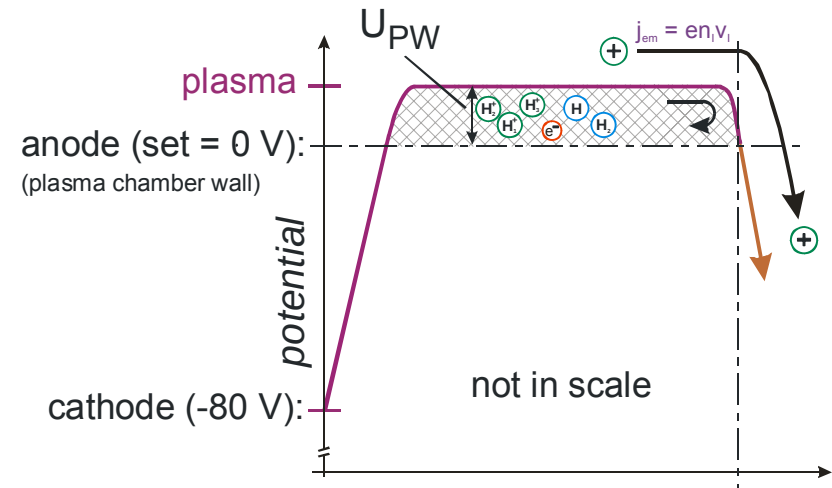


$$\phi_f < \phi_p$$

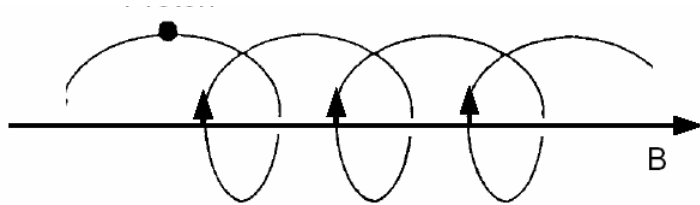
Plasma-wall interface:

- a) ideally reflected
- b) complete wall recombination

→ different mobilities of electrons and ions lead to a positive potential of the plasma towards the wall



Magnetic confinement



$$\omega_c = \frac{q}{m} B$$

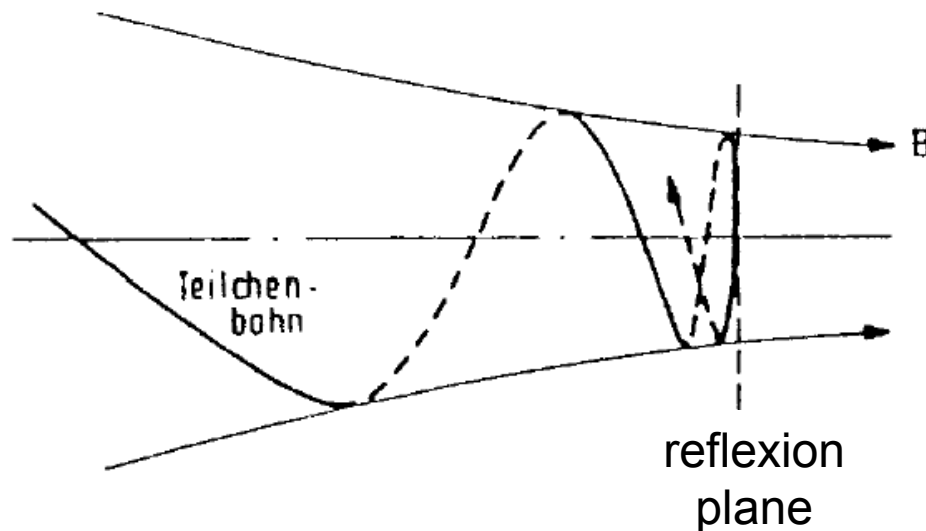
cyclotron frequency

If a charged particle moves into a zone with stronger magnetic field, the kinetic energy of the gyration increases!

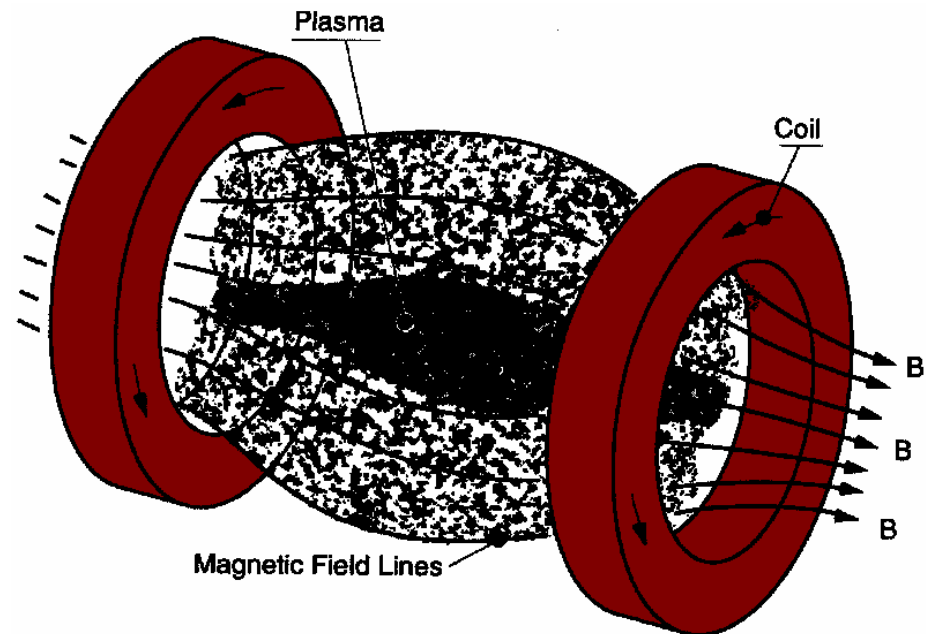
→ total kinetic energy is constant, therefore the particle is decelerated in B-field direction

$$r = \frac{m \cdot v_{\perp}}{q \cdot B}$$

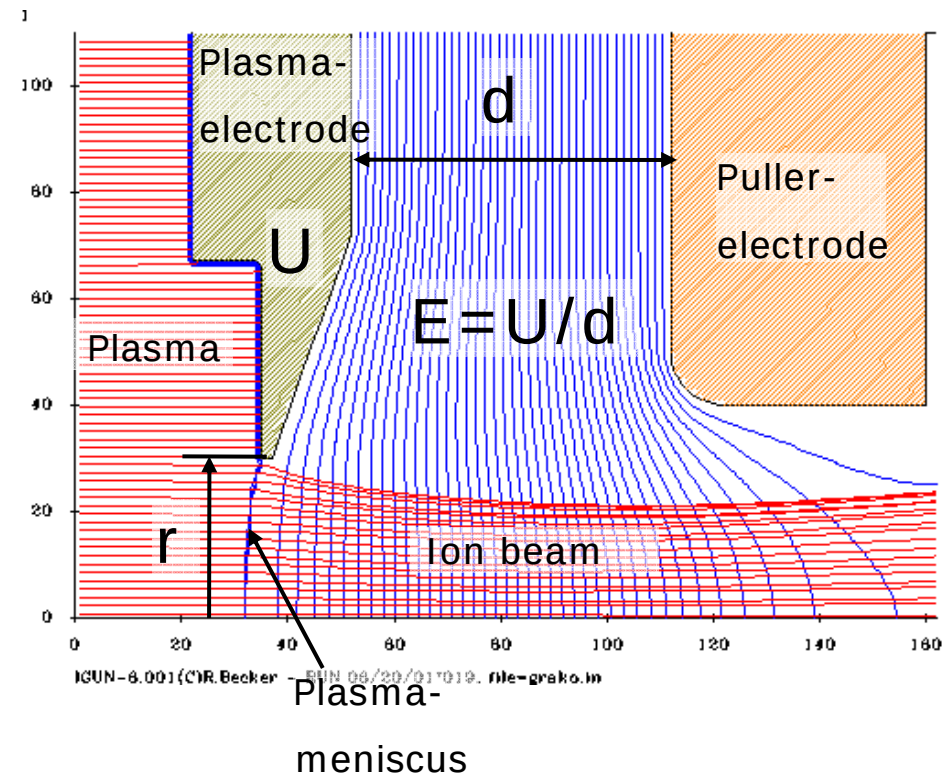
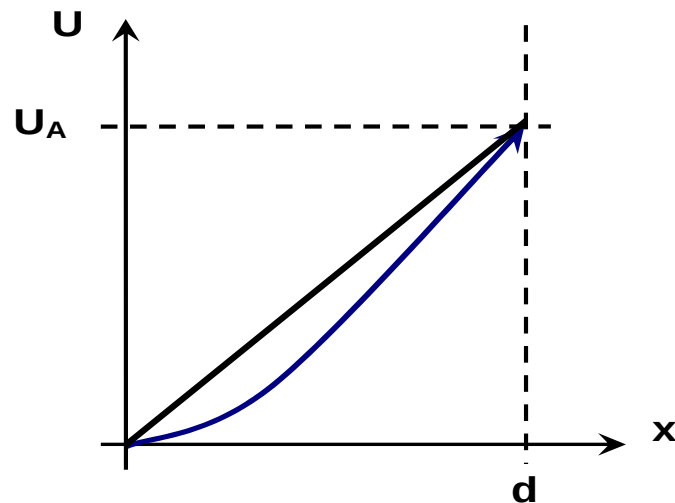
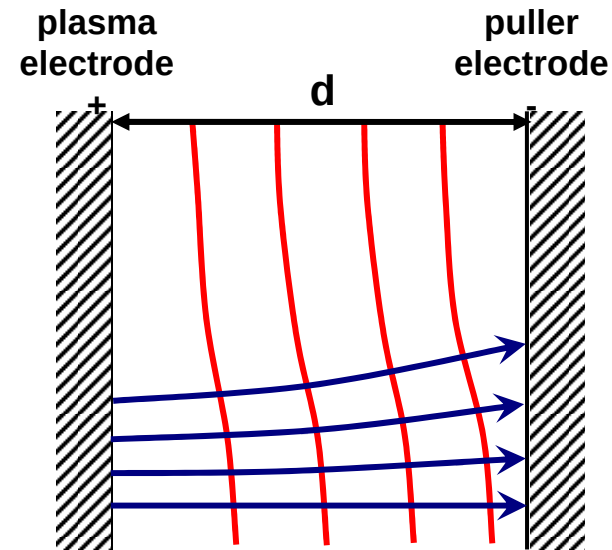
gyration radius



magnetic mirror



Child-Langmuir-Law

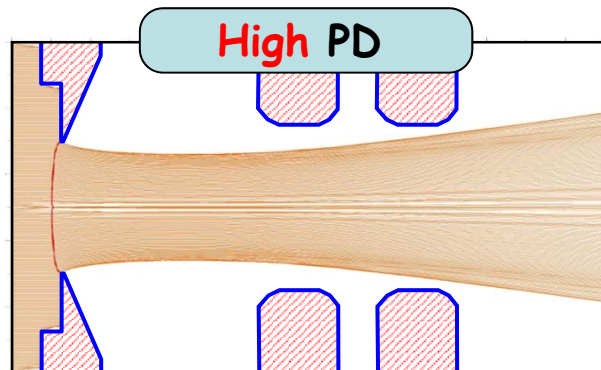
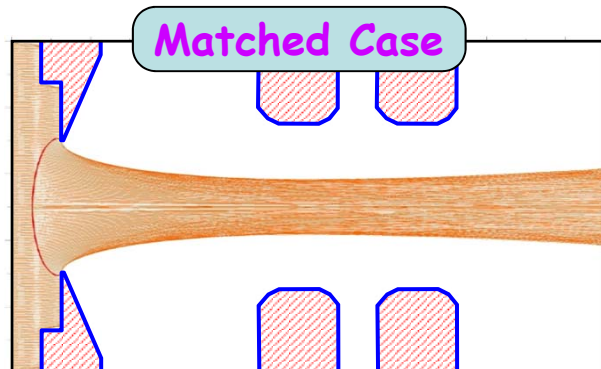
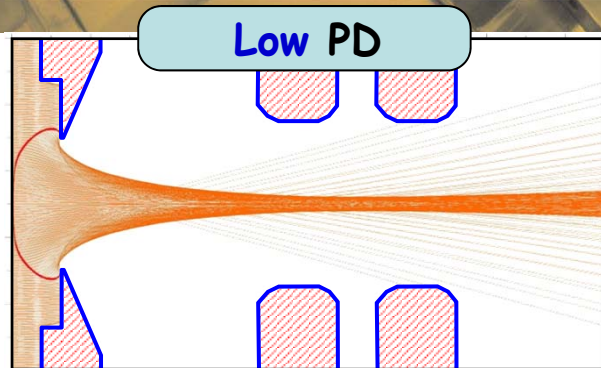


$$I = \frac{4\pi}{9} \epsilon_0 \sqrt{\frac{2qe}{A \cdot m_u}} \cdot r^2 \frac{U^{3/2}}{d^2}$$

$$I = P \cdot U^{3/2}$$

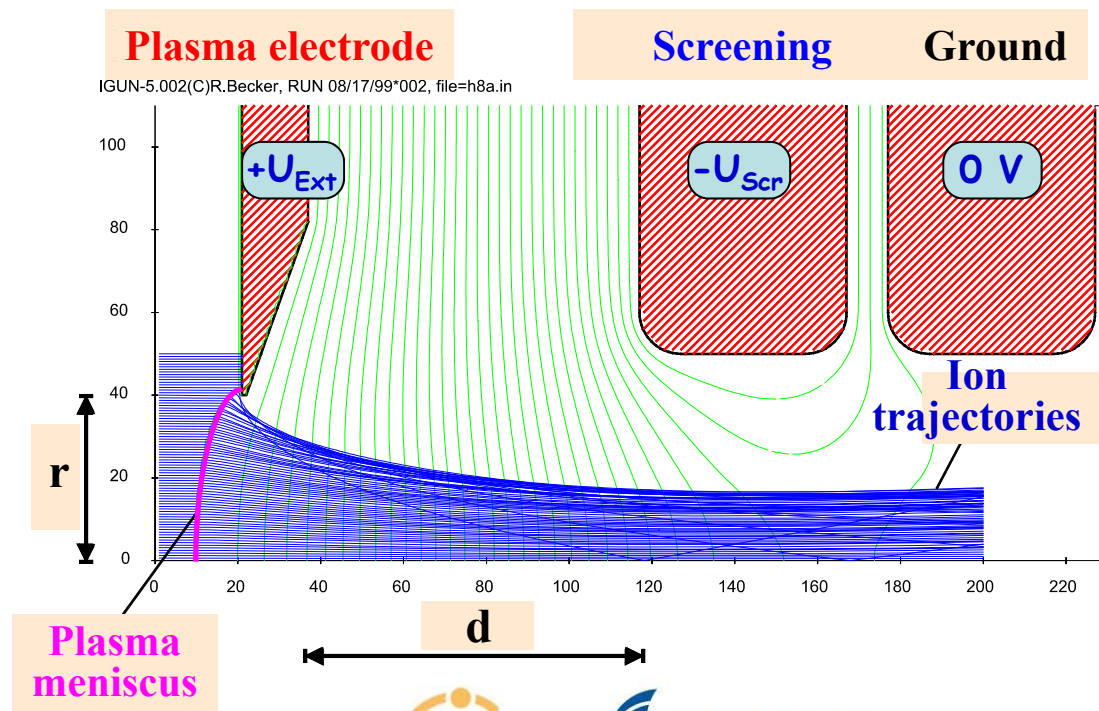
P = Perveance

Ion extraction

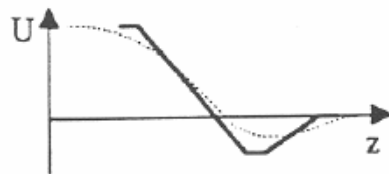
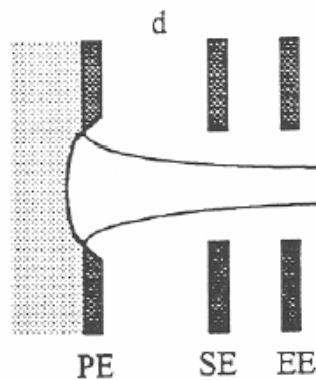


$$S = r/d \quad \text{aspect ratio}$$

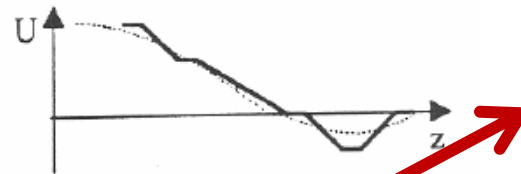
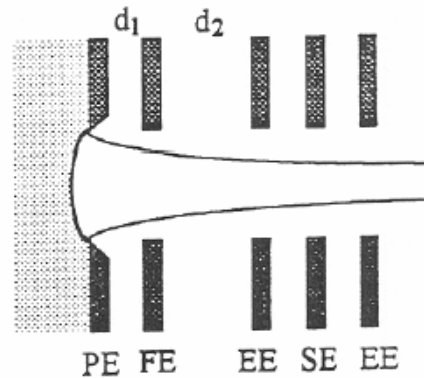
$$I = \frac{4\pi}{9} \varepsilon_0 \sqrt{\frac{2eq}{m_i}} \cdot U^{3/2} S^2 = 1.7 \cdot 10^{-7} \sqrt{\frac{q}{A}} \sqrt{S} \cdot r^{3/2} E^{3/2}$$



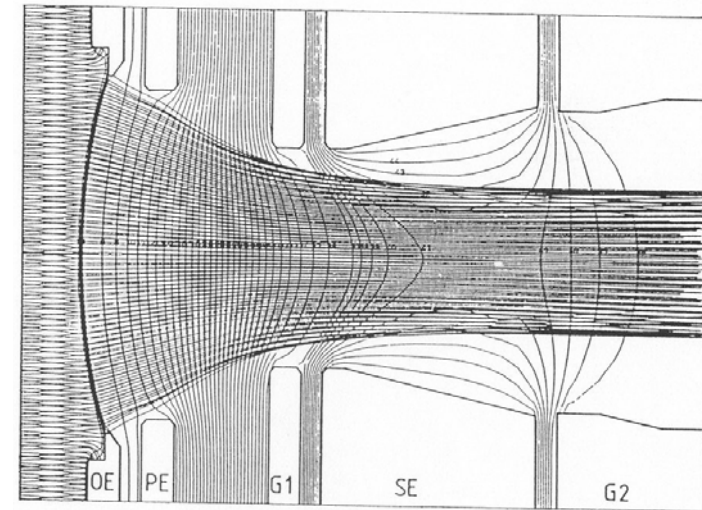
Extraction Systems



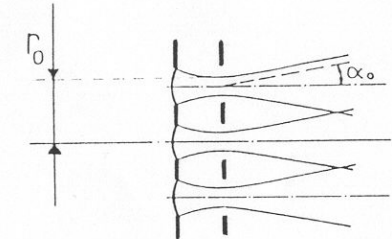
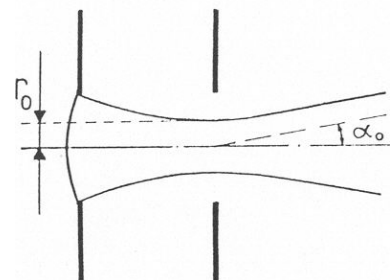
Triode extraction system → most simple system for preservation of space charge compensation.



Pentode extraction system → Formation electrode (FE) + Einzellens set-up



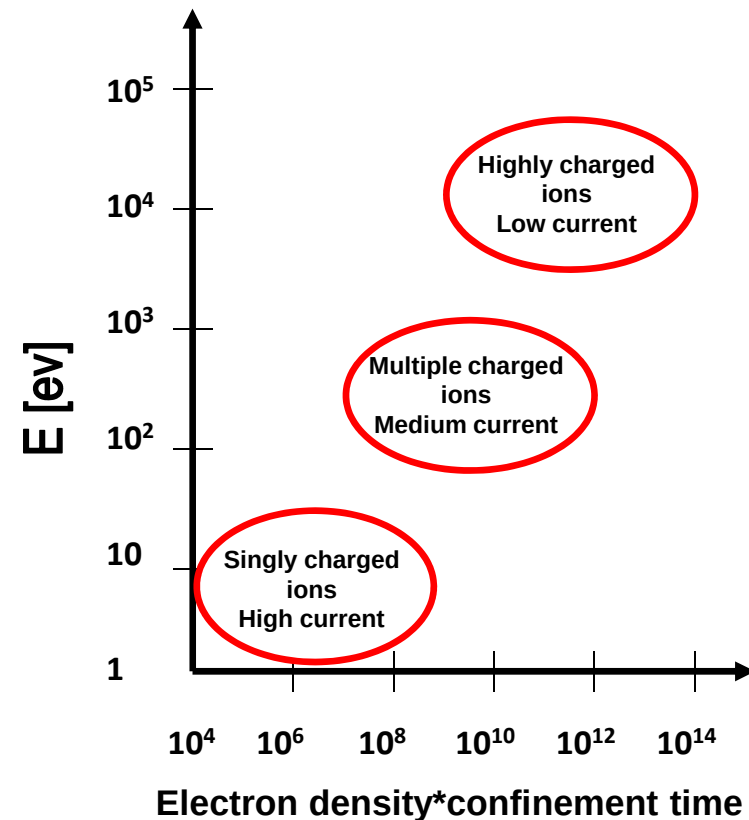
single and multi-aperture extraction
→ to overcome the current limit for a single-aperture extraction system



Classification of ion sources

- The electron energy determines the maximum charge state that can be reached by electron impact ionisation.
- The density*confinement time determines the time required to reach a certain charge state

If the confinement time is too low, the ion species gets lost before reaching the required charge state!

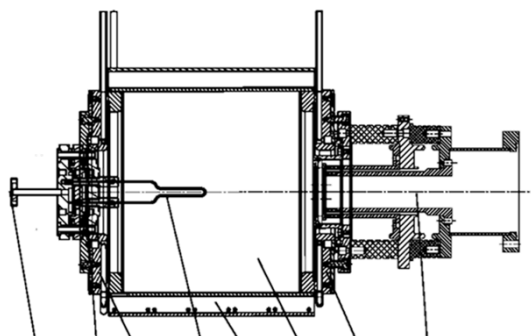




High current ion sources

Overview - high current sources

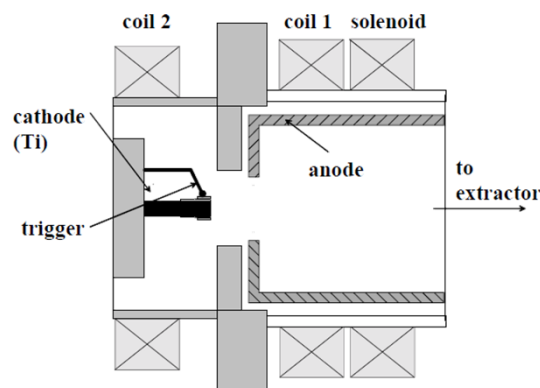
Filament driven



**MUCIS, MUCIS New,
CHORDIS**

**Working material:
Gases**

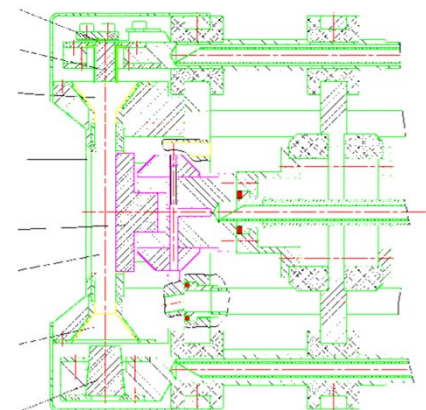
Vacuum Arc driven



MEVVA, VARIS

Metalls and Gases

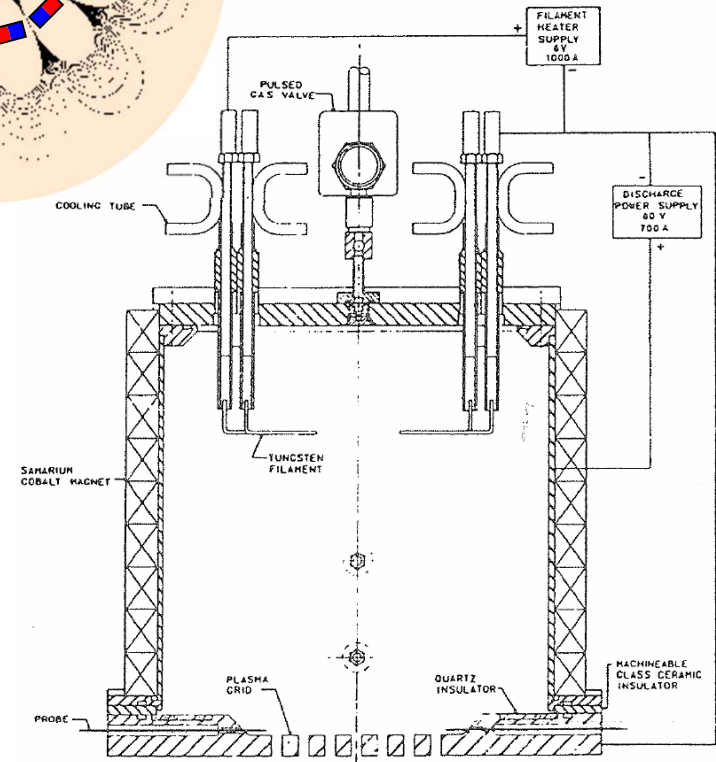
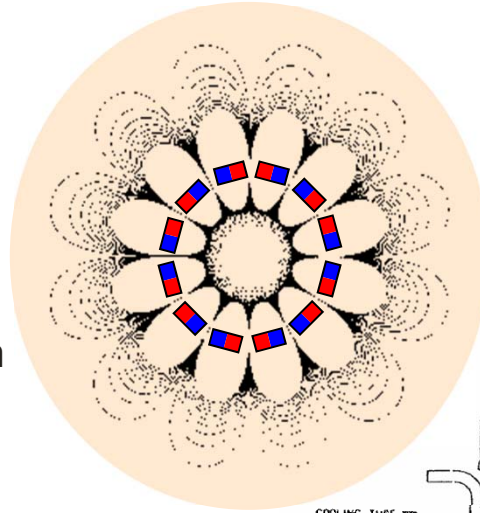
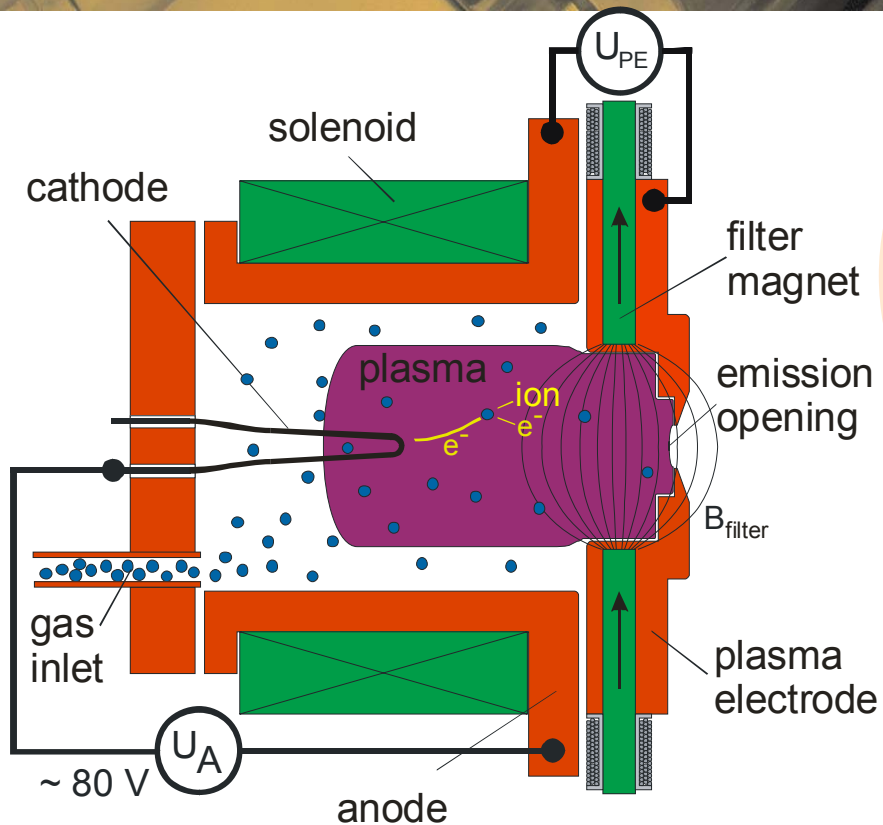
High Duty factor



PIG

Metalls and Gases

Volume source – multicusp source



typical operation parameters (hydrogen):

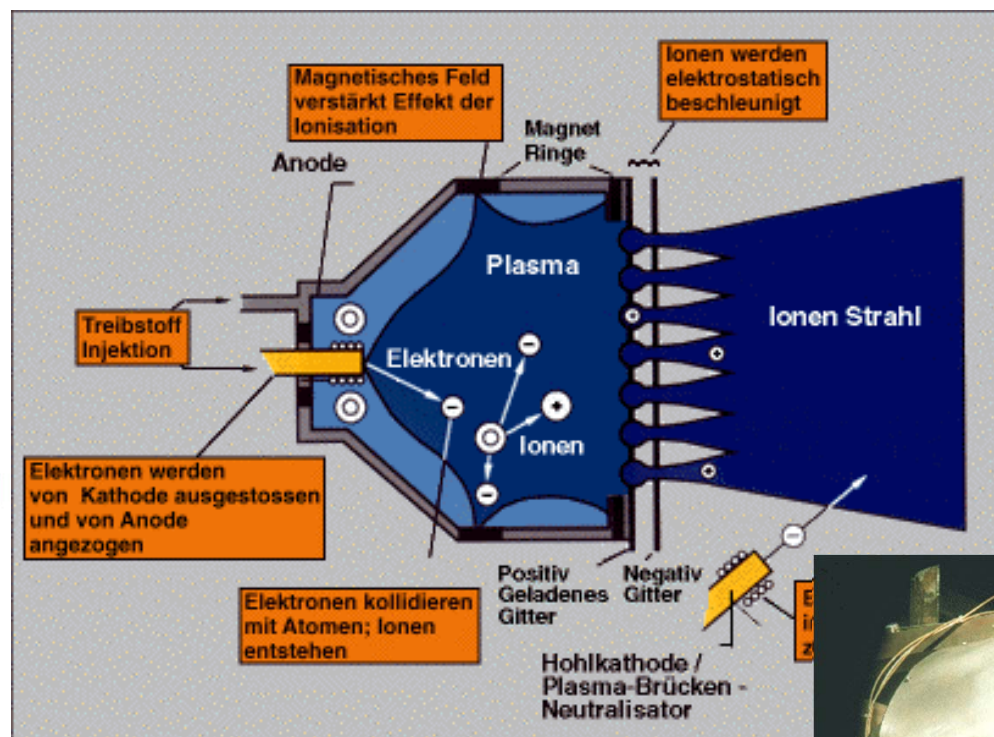
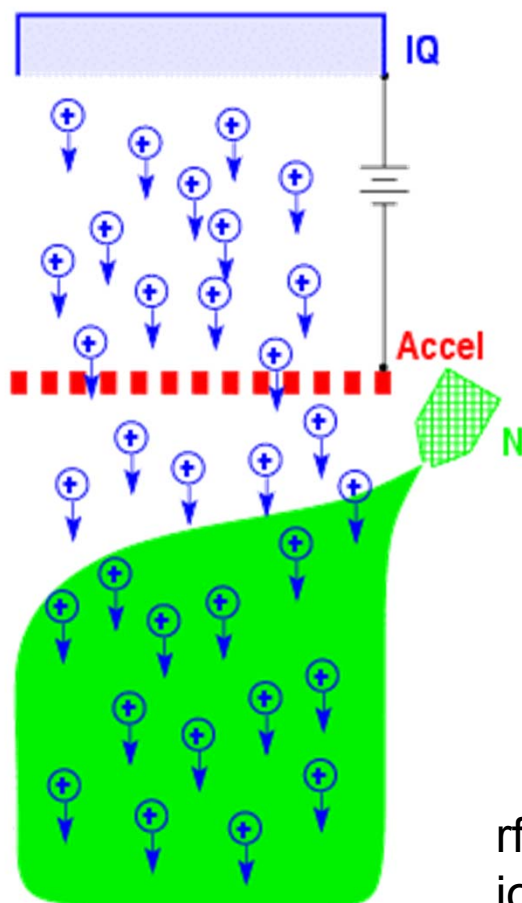
U_A : ~ 80 V, I_A : < 80 A

U_{PE} : < -150 V, I_{PE} : < 25 A

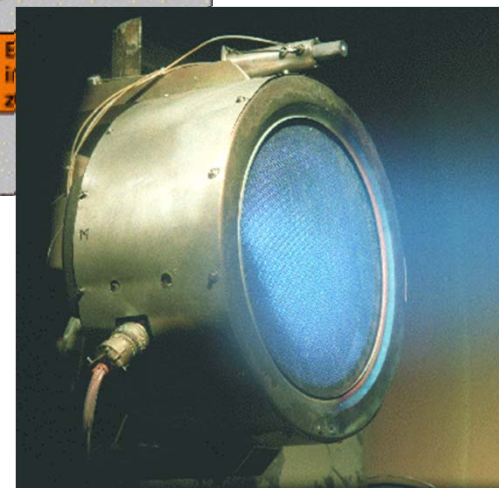
P_{arc} : < 10 kW, p_s : $10 - 75$ Pa

B_{sol} : ~ 25 mT

Special type of volume sources



rf-volume sources as
ion propulsion device
(ion thruster)



Plasmageneration via rf - injection

- Pressure region:
 $10^{-2} - 10^{-3}$ hPa
- $f \leq \nu_{e,n}$
- $\lambda_e < L$
- rf-power $\sim$ kW
- $f = 1-100$ MHz

$$E = E_p \sin(\omega t)$$

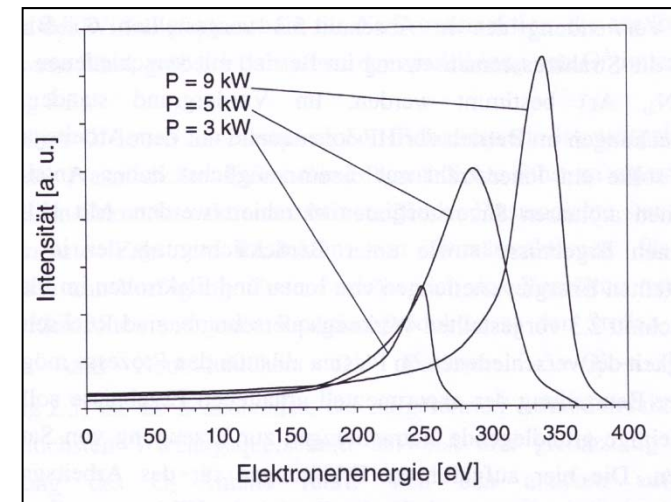
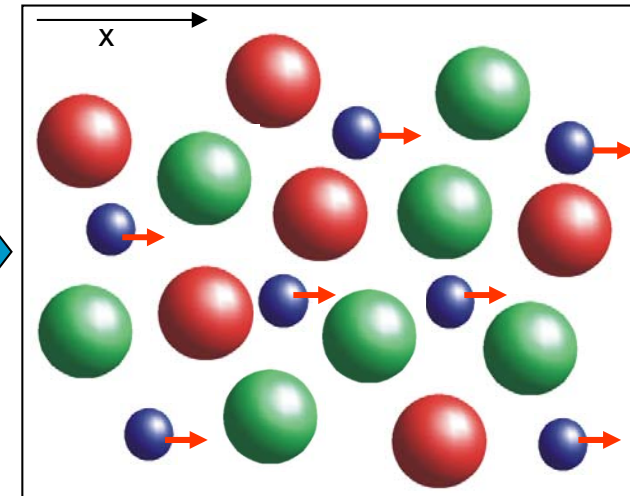
HF

$$m_e \frac{dv}{dt} = eE_p \sin(\omega t + \phi)$$

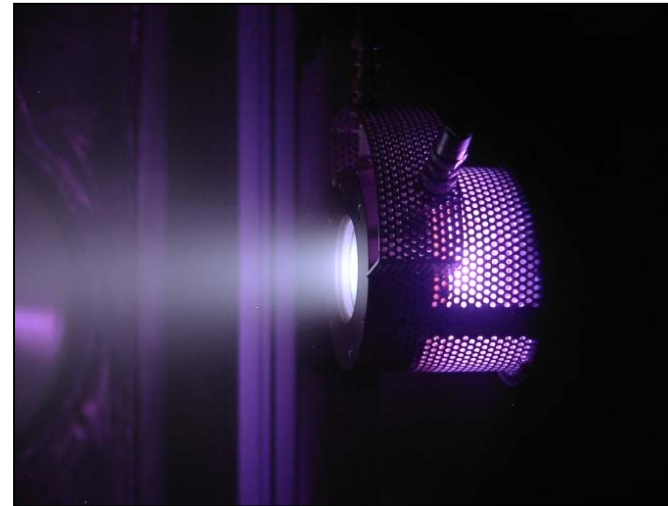
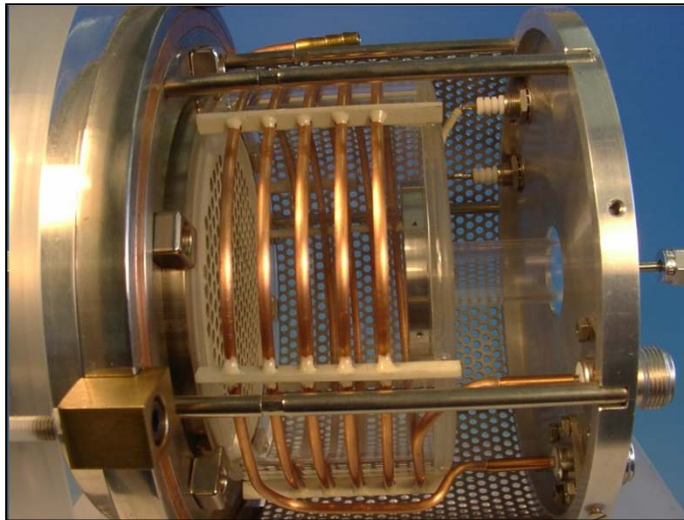
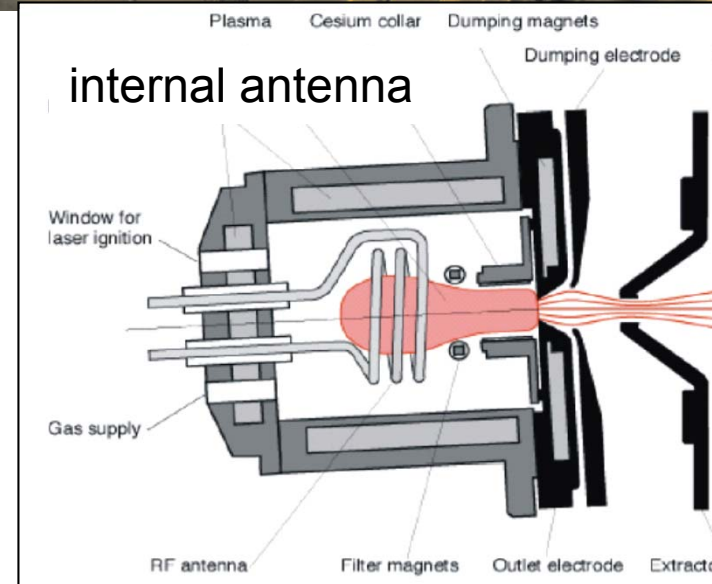
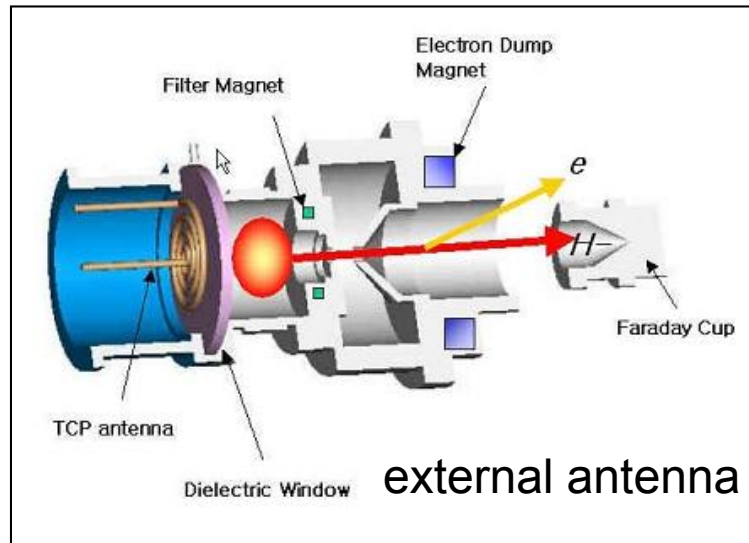
$$v = v_0 + \frac{eE_p}{m_e \omega} [\cos \phi - \cos(\omega t + \phi)]$$

Without collisions, the electrons do not take energy out of the rf-field!

The phase of the electron movement can be changed by collisions. New electrons are generated by ionization processes. If the production rate is bigger than the loss rate, a stable rf-discharge follows.

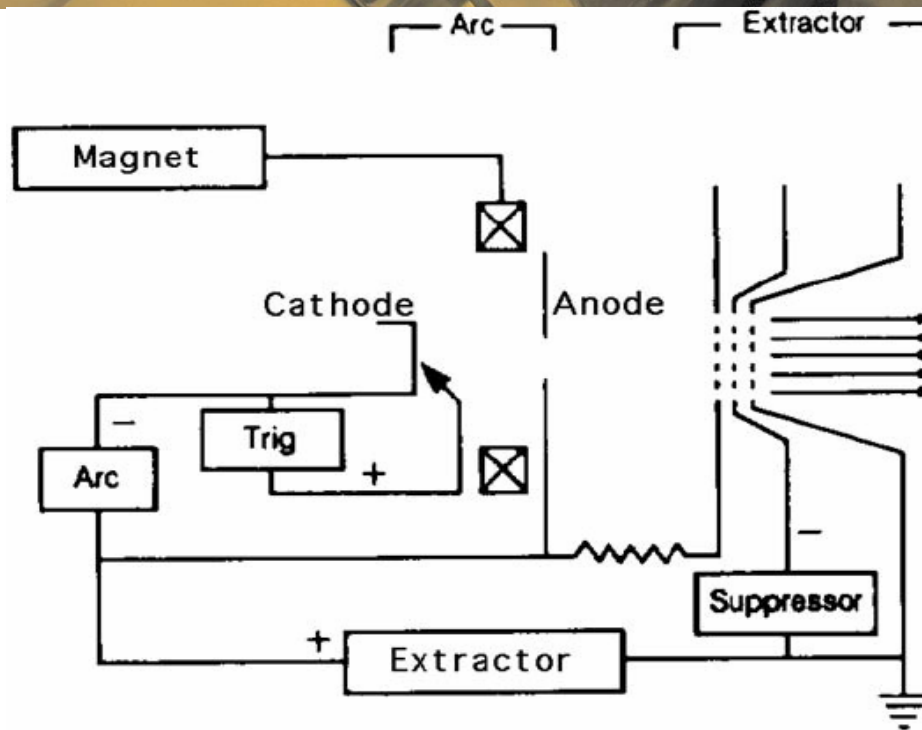


rf – ion sources



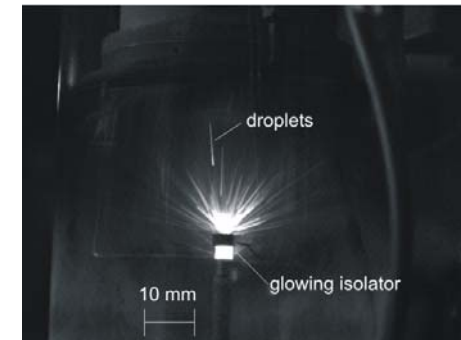
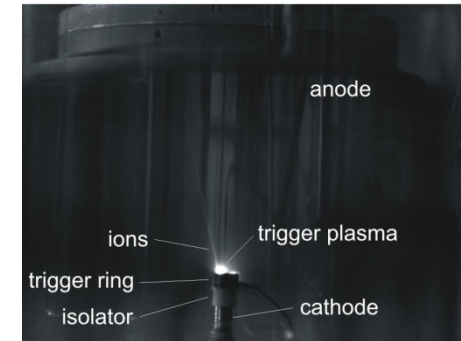
Vacuum arc driven sources

R. Hollinger



The MeVVa-ion source (**M**etal **V**apor **V**acuum **A**rc) produces intense current of multi-charges metallic ions.

- Discharge between the hot cathode and the cold trigger generates the „Metal Vapor“.
- The discharge between the cathode and the anode generates the plasma.



GSI MeVVA source in operation

Cathode: Ti

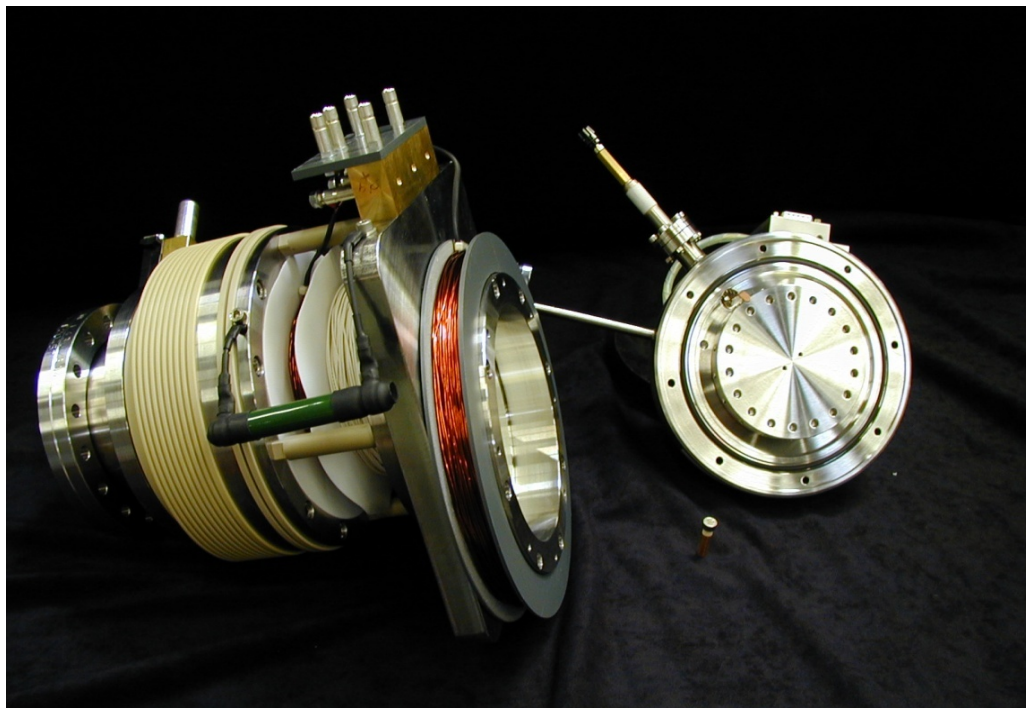
100 μ s after Switching OFF

$I_{\text{Arc}} = 1000 \text{ A}$

R. Hollinger



VARIS (Vacuum Arc Ion Source)



17 cathodes
2 solenoids (0,1 and 0,2 Tesla)
Arc power: 50 kW (13,3 MW/cm²)
Arc current: ~1 kA
Duty cycle: usually 1 Hz, 1 ms

➤ Optimized for Uranium (67% of ²³⁸U⁴⁺)

➤ Emission current density
170 mA/cm²

→ 156 mA @ 32 kV
55 mA @ 131 kV
20 mA in front of the RFQ



Challenges:

- Improving the beam quality at plasma extraction
- Lifetime of cathodes
- 3 Hz operation



High charge state ion sources

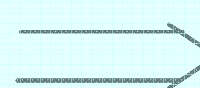
Production of multi-charged ions

Charge state stripper

Stripper foil

Fast ions
+++++

Slow electrons



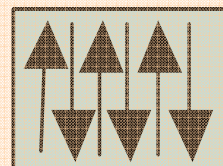
MI

Ion sources

ECR plasma

Slow ions
+++

Fast electrons

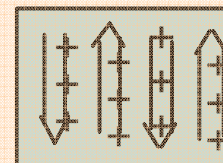


MI

EBIS beam

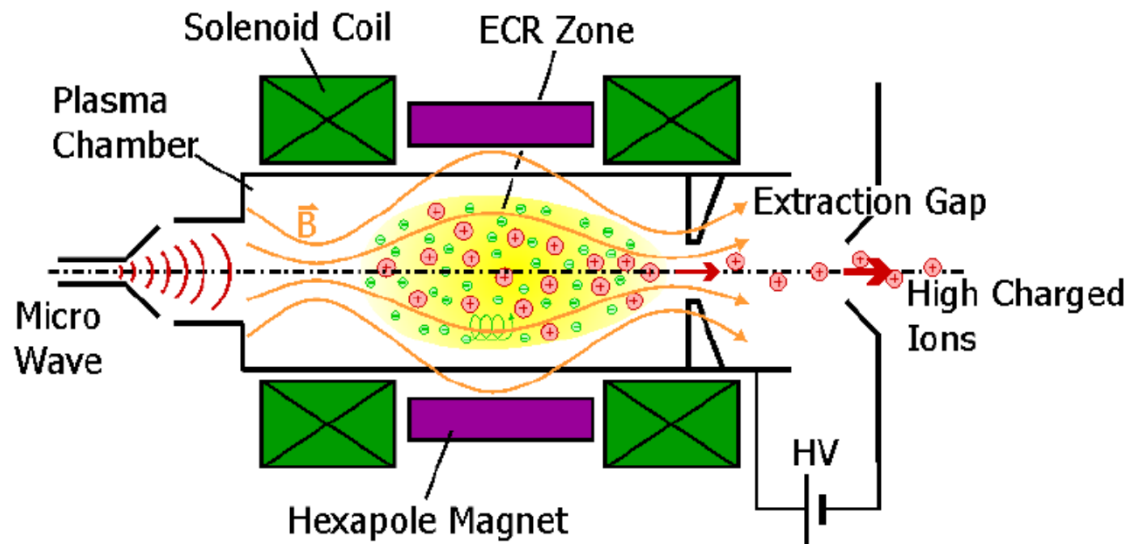
Fast electrons

Slow ions



MI

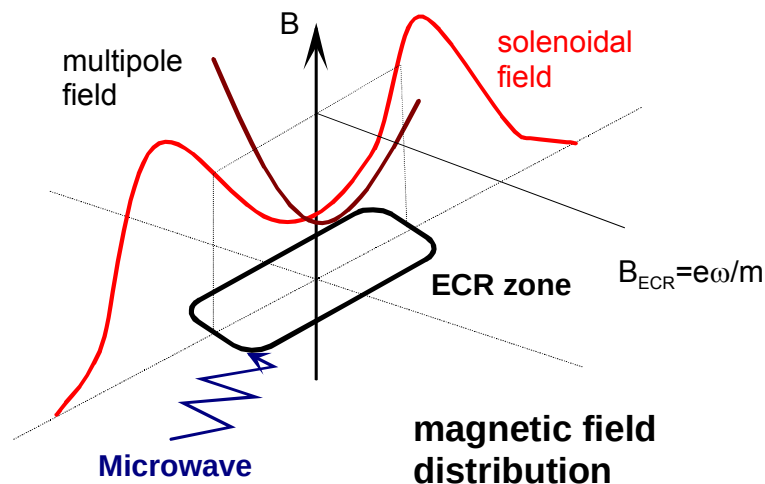
Electron Cyclotron Resonance ion source (ECRIS)



- Resonant microwave plasma heating
- Magnetic confinement
- Higher frequency (28 GHz) higher $B_{\text{ECR}} \sim f$

Challenges:

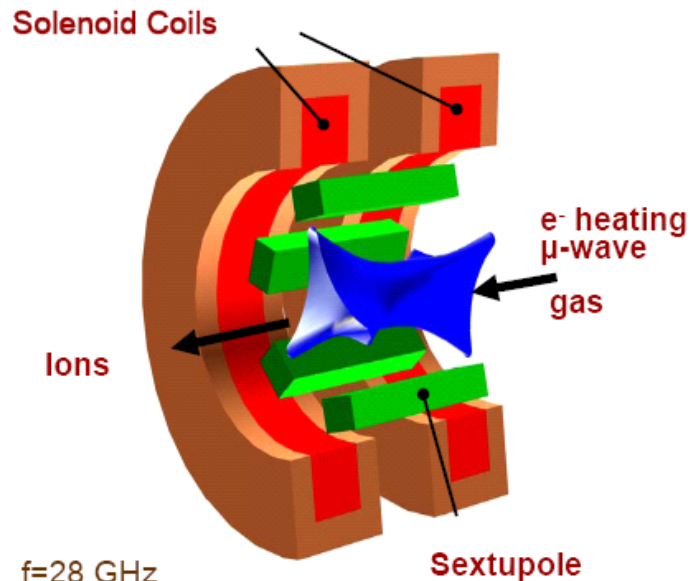
- Magnetic field
- Ion extraction and beam transport



$$\omega_c = \frac{e}{m_e} B \Rightarrow$$

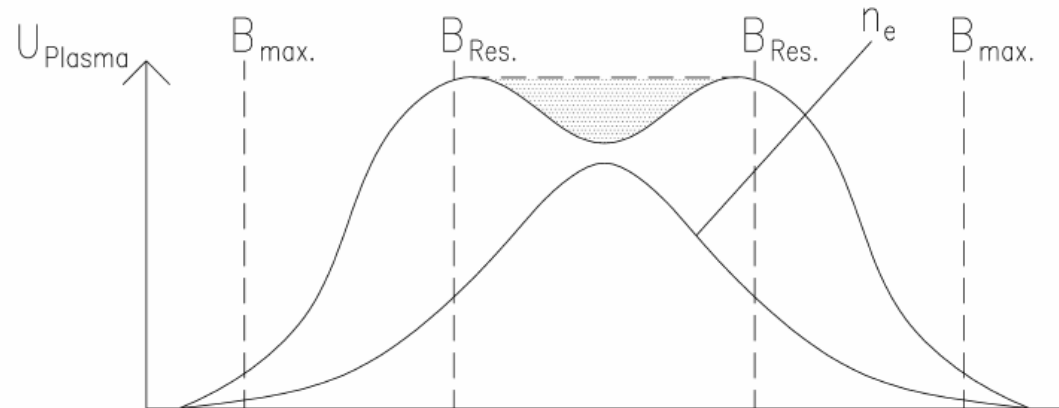
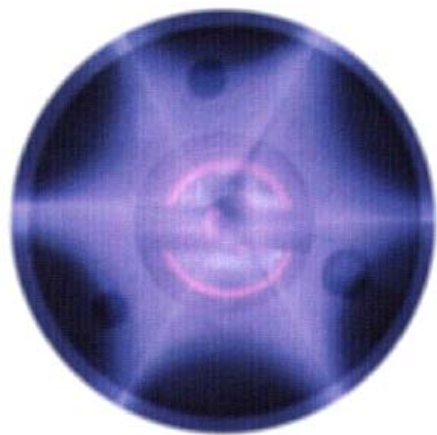
$$f = \frac{eB}{2\pi \cdot m_e} = 2.796 \cdot 10^{10} \cdot B[T]$$

ECRIS basics



$f=28 \text{ GHz}$

$B_{\text{resonance}} = 1 \text{ T}$



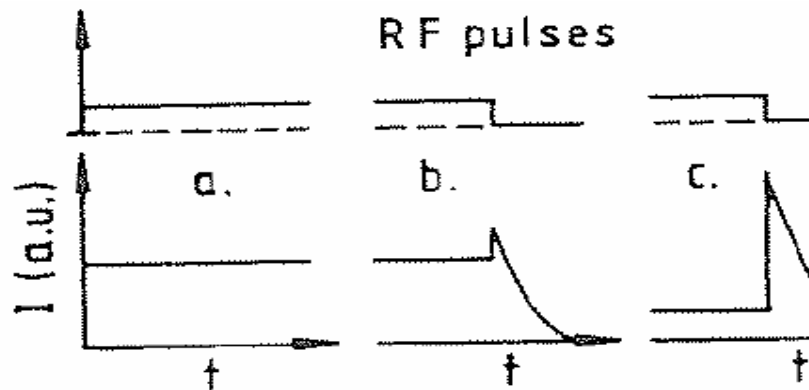
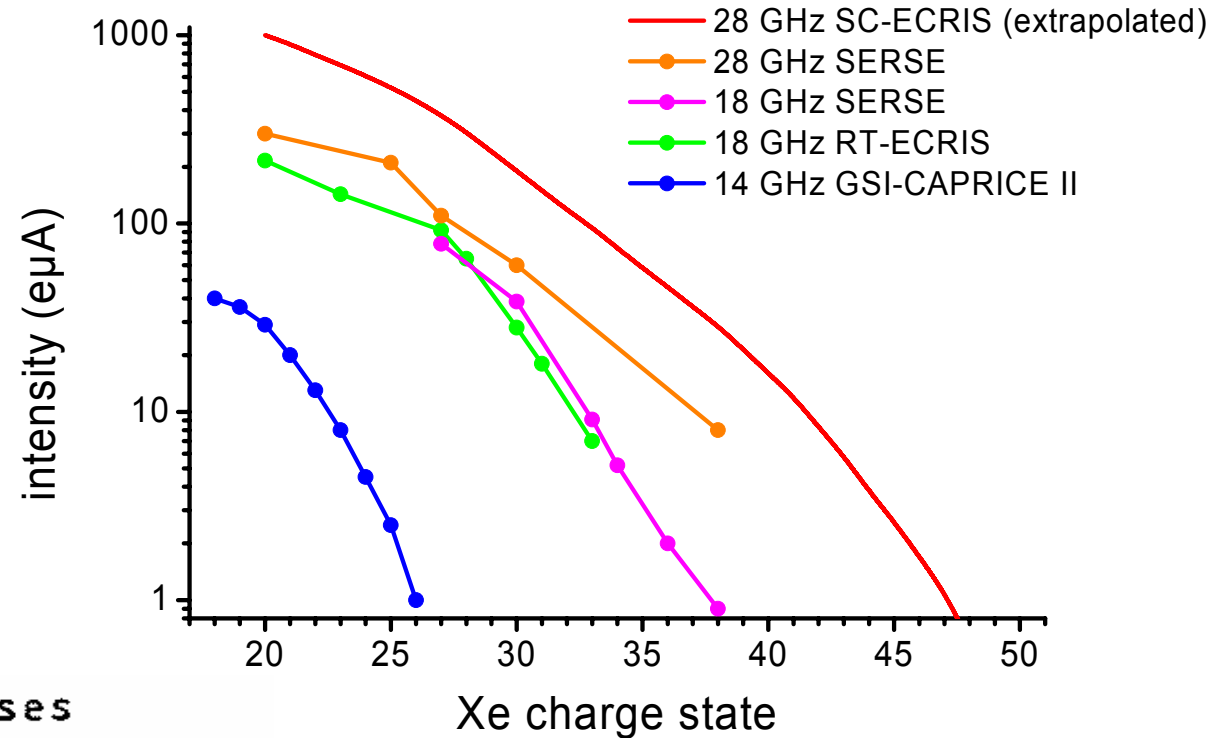
- Variation of the plasma potential
- Intense heating of electrons → MeV energies

The following magnetic-field relations are valid for high power ECRs:

$$B_{\text{inf}}/B_{\text{ecr}} \sim 4, B_{\text{ext}}/B_{\text{ecr}} \sim 2, B_{\text{min}}/B_{\text{ecr}} \sim 0.8, \\ B_{\text{rad}}/B_{\text{ecr}} \geq 2, B_{\text{ext}}/B_{\text{rad}} \leq 0.9$$

ECRIS scaling laws and ion intensities

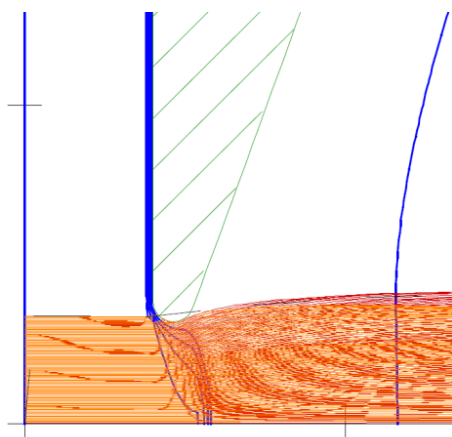
$$\begin{aligned}
 n_e &\propto \omega_{rf}^2 \\
 \tau_{ion} &\propto B_{max}/B_{min} \\
 I &\propto \omega_{rf}^2/M \\
 I &\propto n_{ion} / \tau_{ion} \\
 I &\propto P_{rf}^{1/3}
 \end{aligned}$$



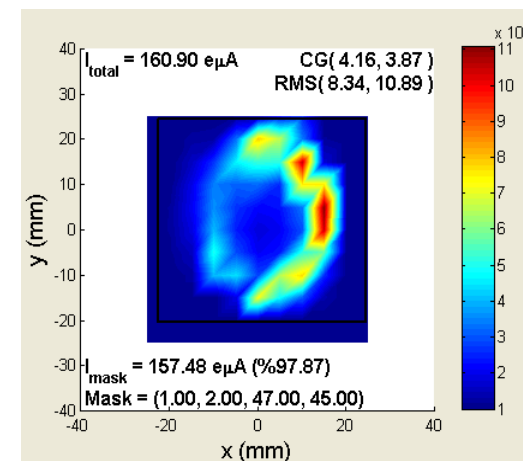
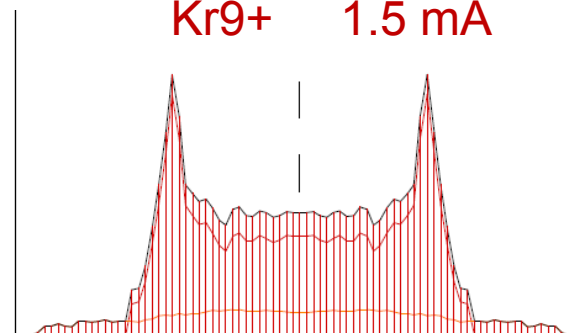
ECRIS is usually running cw
 → pulse operation in “afterglow mode”

Plasma boundary and profile

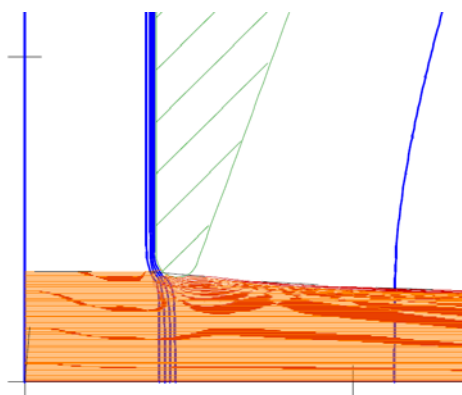
Mismatched extraction



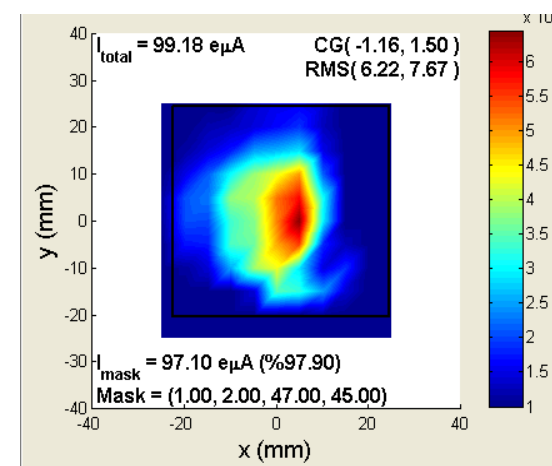
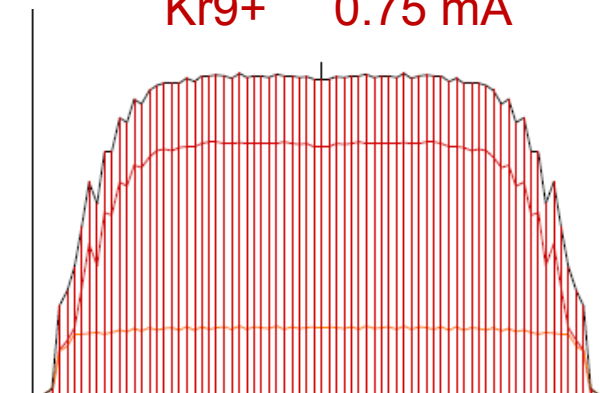
Kr17+ 0.5 mA
Kr9+ 1.5 mA



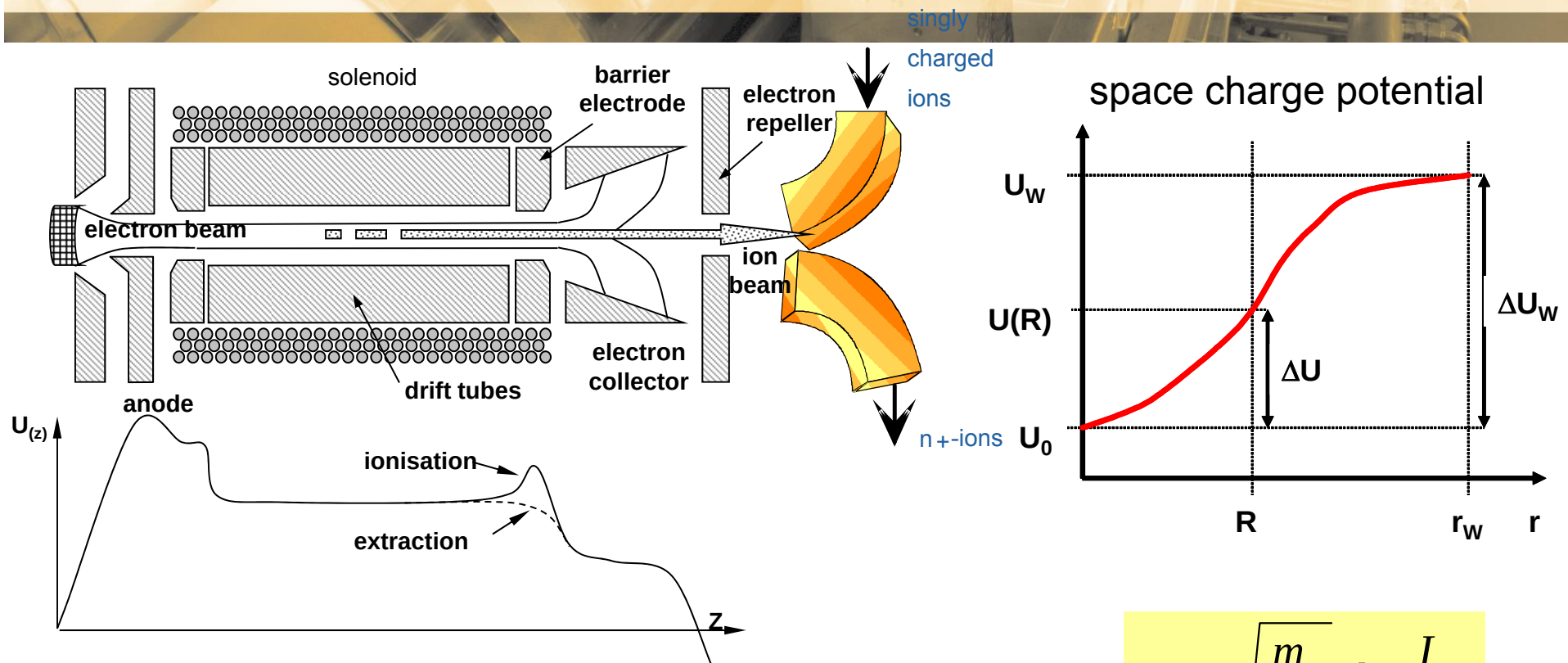
Matched extraction



Kr17+ 0.25 mA
Kr9+ 0.75 mA



Electron Beam Ion

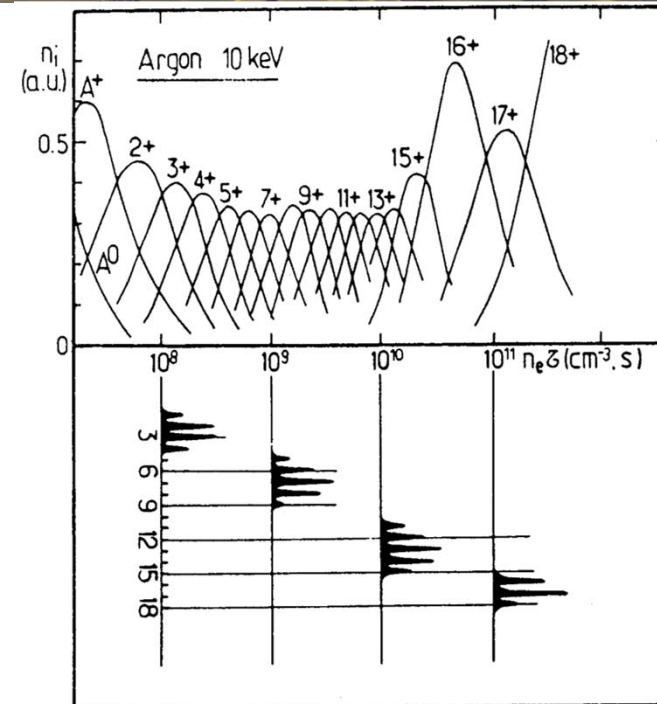
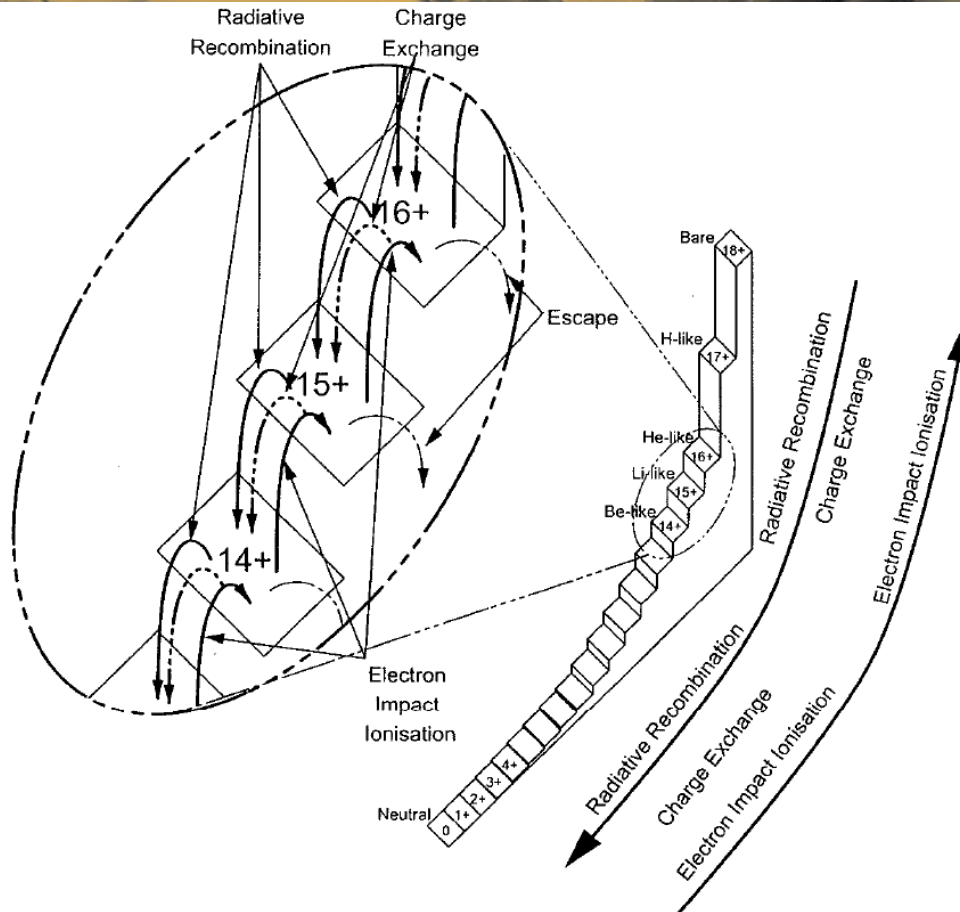


- Electrostatic confinement
- Intense electron beam (current density, up to 10^4 A/cm²)
- Tunable electron beam energy
- Storage capacity ~ trap length, electron current

$$N^- = \sqrt{\frac{m_e}{2e^3}} \cdot l \cdot \frac{I_e}{\sqrt{U_e}}$$

I_e = electron beam current
 U_e = electron beam energy
 l = length of confinement region

Charge state development in an EBIS/T



Charge development for stepwise ionisation

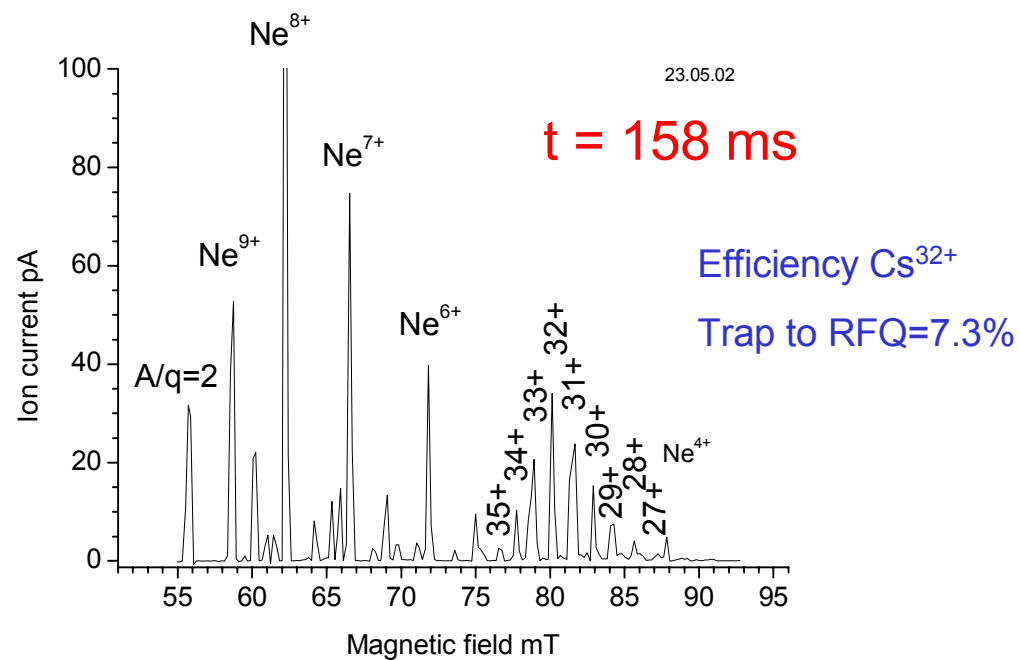
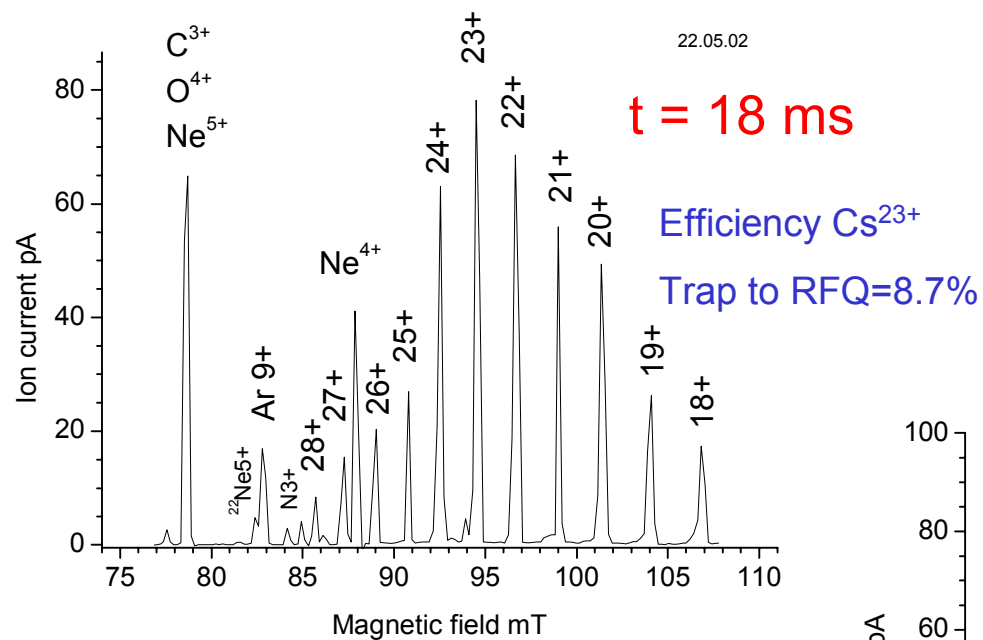
$$\frac{dn}{dt} = \text{Sources} - \text{Drains}$$

example

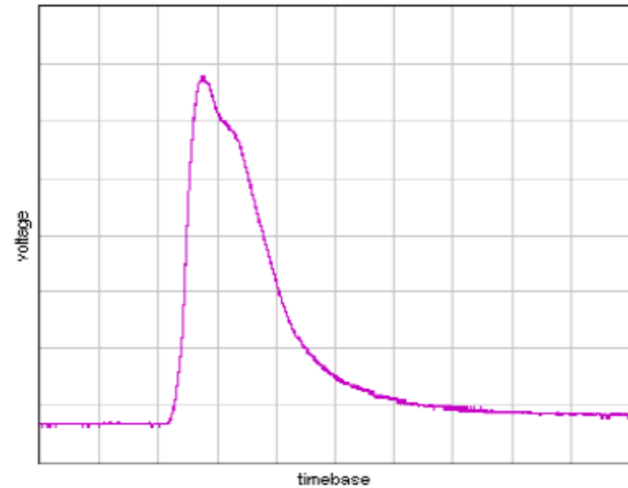
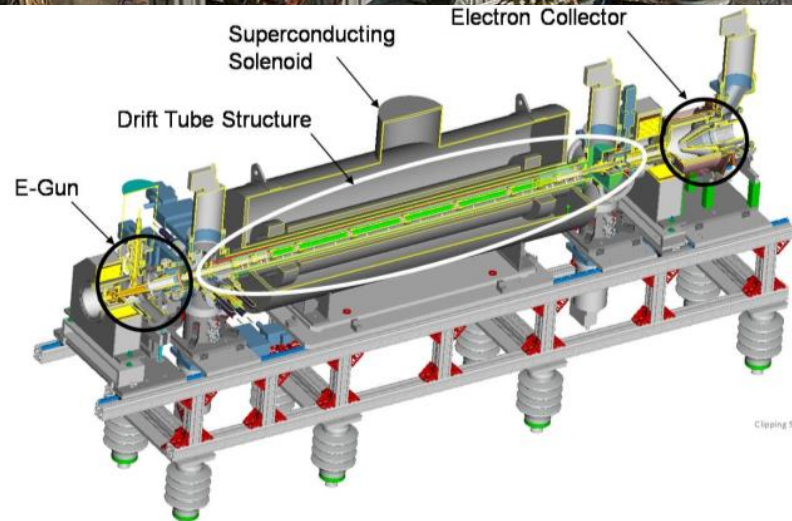
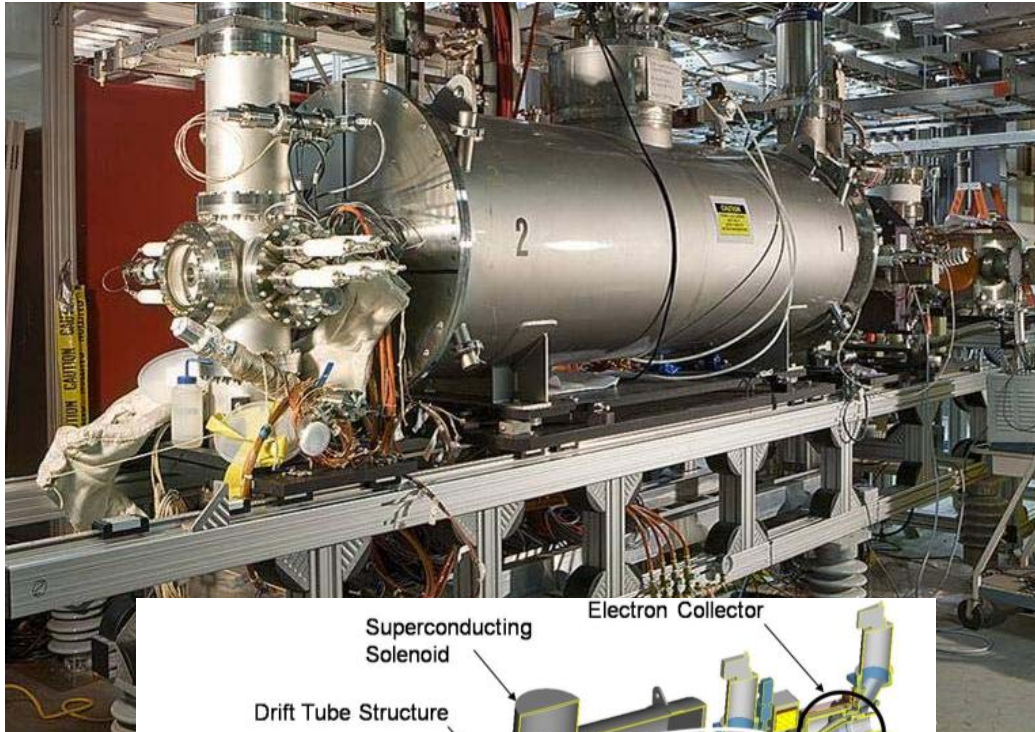
$$\frac{dn_{z+1}}{dt} = n_e \cdot n_z \cdot v_e \sigma_{z \rightarrow z+1} - n_e \cdot n_{z+1} \cdot \sigma_{z+1,RR}$$

Electron impact ionisation Radiative recombination (RR)

Extracted ion beams - example



RHIC EBIS / BNL – Intense pulses of HCIs



6 mA Au pulse;
 $\sim 2.6 \times 10^9$ Au³²⁺ / pulse

Maximum B-field	5.0 T
“Warm” ID	204 mm
Length of solenoid	1900 mm
He refilling period	30 days

Top-ten reasons for „why it's great to be an ion source physicist“

10. Spouses never need to worry about what their ion source physicist husband or wife is up to when they still aren't home by midnight...they know with great confidence that they're just at the lab changing a source!

9. Between

- the International Conference on Ion Sources,
- the Workshop on Ion Source Issues Relevant to a Pulsed Spallation Neutron Source,
- the ECR Ion Source Workshop,
- The International Conference on Negative Ions, Beams and Sources,
- the International Symposium on the Production and Neutralization of Negative Ions and Beams,
- the Workshop on Negative Ion Formation and Beam Handling,
- the International Conference on Sources of Highly Charged Ions,

the ion source community has the greatest number of conferences and workshops of any scientific discipline measured per linear inch of subject matter

8. Endless hours can be devoted to the important philosophical meaning of “pi” as in “the output emittance is 0.2 pi-mm-mrad”

7. Believe it or not, sometimes the rf-ion source antenna picks up free Satellite Television!

6. High-voltage, hydrogen gas, antennas and power supplies: it's every little kids dream!

5. In what other field can you acquire a Ph.D., and then spend your professional life practicing the occult?

4. When the phone rings during dinner time, you always know who it is: no its not a tele-marketer, it just the lab...the ion source went down!

3. In what other field could you advertise a workshop on “RF-driven, multicusp, Cesium-enhanced H-sources”, and have 50 people actually show up?

2. Job security...when was the last time you heard a manager say, “the ion source is running so well, we're going to let the entire group go.”

1. It's a subject in which anyone can make a contribution, and everyone has an opinion!

Courtesy of Stuart Stuart Henderson/ORNL